



Programmable Serial Interface

PRELIMINARY(High Speed Devices)

Programmable Bandwidth

Features

- 200 Mbps – 1.5 Gbps, 2.5 Gbps serial signaling rate
- Flexible parallel-to-serial conversion in transmit path
- Flexible serial-to-parallel conversion in receive path
- Multiple selectable loopback/loop-through modes
- 100K to 200K usable gates of CPLD logic
- 240K to 480 Kb of integrated memory
 - 192K to 384Kb of synchronous or asynchronous SRAM
 - 48K to 96Kb of true Dual-Port or FIFO RAM
- Internal transmit and receive PLLs
- Logic dedicated Spread Aware PLL
- Transmit FIFO for flexible variable phase clocking
- Differential CML serial input with internal termination and DC-restoration
- Differential CML serial output with source matched impedance of 50Ω
- 160–240 user programmable I/Os
- Any Volt™ I/O interface
 - Programmable as 1.8V, 2.5V, 3.3V
- Multiple I/O standards
 - LVCMOS, LVTTTL, 3.3V PCI, SSTL2(I-II), SSTL3(I-II), HSTL(I-IV), and GTL+
- Direct interface to standard fiber-optic modules
- Designed to drive:
 - Fiberoptic Modules
 - Copper Cables
 - Circuit Board Traces
 - Backplane Links
 - Box-to-Box Links
 - Chip-to-Chip Communication
- Extremely flexible clocking options
 - Four global clocks
 - Up to 192 additional product term clocks
 - Clock polarity at every register
- Carry chain logic for fast and efficient arithmetic operations
- Fully PCI compliant (Rev. 2.2)
- JTAG programming interface with boundary scan support
- High-Speed (HS) or Frequency Agile (FA) Programmable Serial Interface™ (PSI™) versions available

High-Speed PSI Features

- 2.5 Gbps/channel serial signaling rate
- Full Bellcore and ITU jitter compliance

Note:

1. For more detail, refer to the "Frequency Agile PSI" data sheet.

- Power-saving mode
- Up to two serial channels available to allow:
 - High-Bandwidth
 - Redundancy
- Supported standards:
 - InfiniBand™
 - SONET OC-48

Frequency Agile PSI Features^[1]

- 200 Mbps–1.5 Gbps serial signaling rate per channel
- Up to eight serial channels available to allow:
 - Frequency Agile
 - Redundancy
- Selectable input and output clocking options
- MultiFrame™ receive framer provides alignment to:
 - Bit, byte, half-word, word, multi-word
 - COMMA or Full K28.5 detect
 - Single or Multi-byte framer for byte alignment
 - Low-latency option
- Skew alignment support for multiple bytes of offset
- Selectable parity check/generate
- Serial Built-In-Self-Test (BIST) for at-speed link testing
- Per-channel Link Quality Indicator
 - Analog signal detect
 - Digital signal detect
 - Frequency range detect
- Supported standards:
 - Fibre Channel
 - Gigabit Ethernet
 - ESCON
 - DVB
 - SMPTE

Development Software

- Warp®
 - IEEE 1076/1164 VHDL or IEEE 1364 Verilog context sensitive editing
 - Active-HDL FSM graphical finite state machine editor
 - Active-HDL SIM post-synthesis timing simulator
 - Architecture Explorer for detailed design analysis
 - Static Timing Analyzer for critical path analysis
 - Available on Windows® 95, 98 & NT for \$99
 - Supports all Cypress programmable logic products



PSI Quick Reference Selection Guide

Logic Gate Density	High-Speed/SONET/SDH PSI Serial Bandwidth		Frequency-Agile PSI Serial Bandwidth	
	1 x 2.5 Gbps	2 x 2.5 Gbps	4 x 0.2 – 1.5 Gbps	8 x 0.2 – 1.5 Gbps
100K	25G01K100	25G02K100	15G04K100	
200K		25G02K200	15G04K200	15G08K200

PSI Family Standards Supported

PSI Device		SONET/SDH (OC48/STM16)	InfiniBand	Fibre Channel	Gigabit Ethernet	ESCON	SMPTE 259/292	Custom
SONET/SDH	CYS25G01K100	X						X
	CYS25G02K100	X						X
	CYS25G02K200	X						X
High Speed	CYP25G01K100		X					X
	CYP25G02K100		X					X
	CYP25G02K200		X					X
Frequency Agile	CYP15G04K100			X	X	X	X	X
	CYP15G04K200			X	X	X	X	X
	CYP15G08K200			X	X	X	X	X

PSI Family General Selection Guide

Device	Typical Gates	Macrocells	Cluster memory (Kbits)	Channel memory (Kbits)	Maximum User Programmable I/O	Package Offering
25G01K100	46K–144K	1536	192	48	240	456-BGA (35x35 mm, 1.27 mm pitch)
25G02K100	46K–144K	1536	192	48	194	456-BGA (35x35 mm, 1.27 mm pitch)
25G02K200	92K–288K	3072	384	96	320	700-BGA (45x45 mm, 1.27 mm pitch)
15G04K100	46K–144K	1536	192	48	206	456-BGA (35x35mm, 1.27 mm pitch)
15G04K200	92K–288K	3072	384	96	332	700-BGA (45x45 mm, 1.27 mm pitch)
15G08K200	92K–288K	3072	384	96	206	700 BGA (45x45 mm, 1.27 mm pitch)

Shaded areas contain advance information.

PSI Family Performance Selection Guide

Device	Channels & Link Speed	Total Bandwidth	f_{MAX2} (MHz)	Logic Speed— t_{PD} Pin-to-Pin (ns)	Standby $I_{CC}^{[2]}$
25G01K100	1 x 2.5 Gbps	2.5 Gbps	222	7.5	16 mA
25G02K100	2 x 2.5 Gbps	5.0 Gbps	222	7.5	22 mA
25G02K200	2 x 2.5 Gbps	5.0 Gbps	181	8.5	22 mA
15G04K100	4 x 0.2 – 1.5 Gbps	6.0 Gbps	222	7.5	18 mA
15G04K200	4 x 0.2 – 1.5 Gbps	6.0 Gbps	181	8.5	18 mA
15G08K200	8 x 0.2 – 1.5 Gbps	12.0 Gbps	181	8.5	26 mA

Note:

- Standby I_{CC} values are with logic PLL not utilized, no output load, and stable inputs.
- Shaded area is preliminary

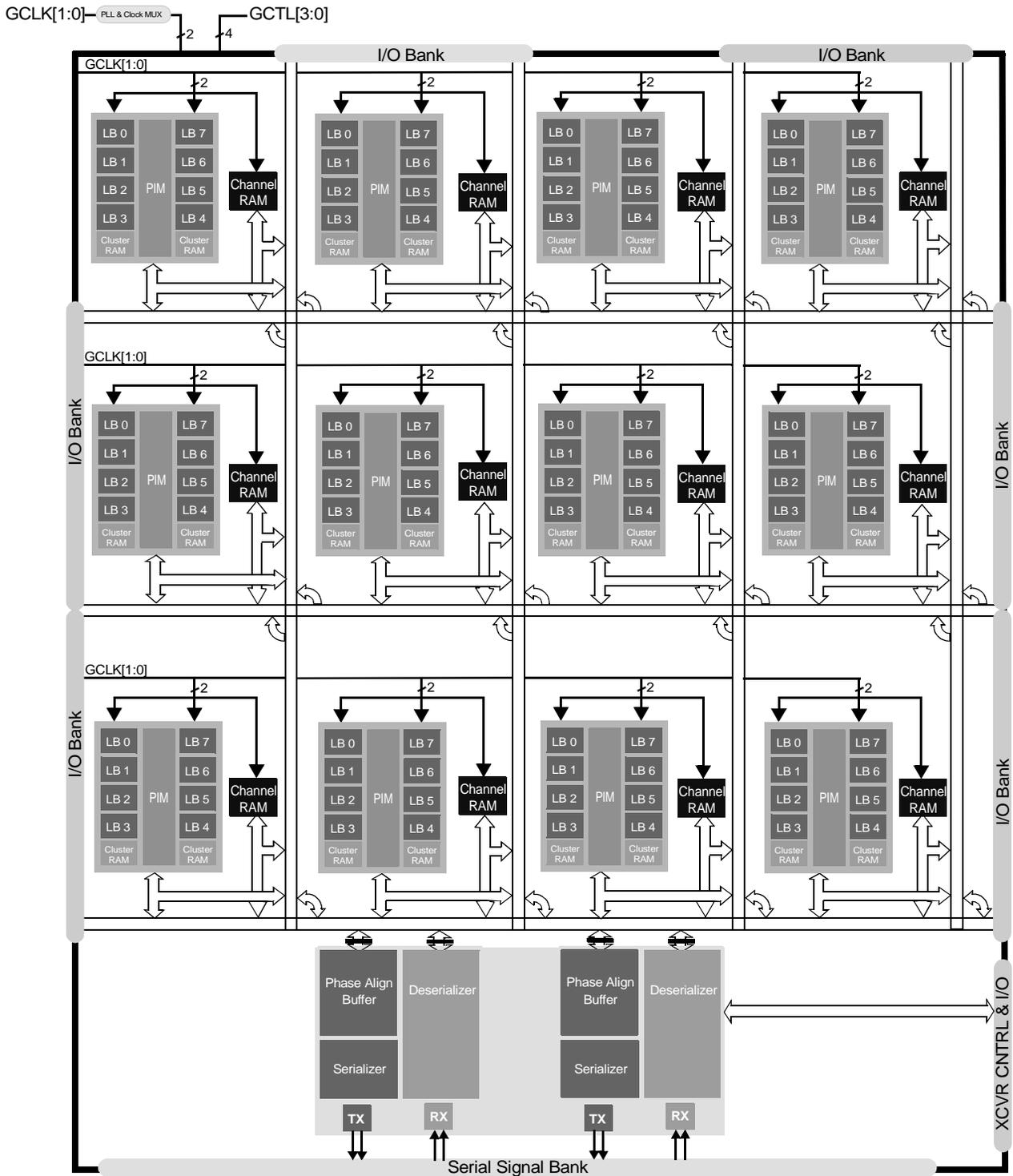


Figure 1. High-Speed PSI™ Block Diagram (25G02K100) with I/O Bank Structure.

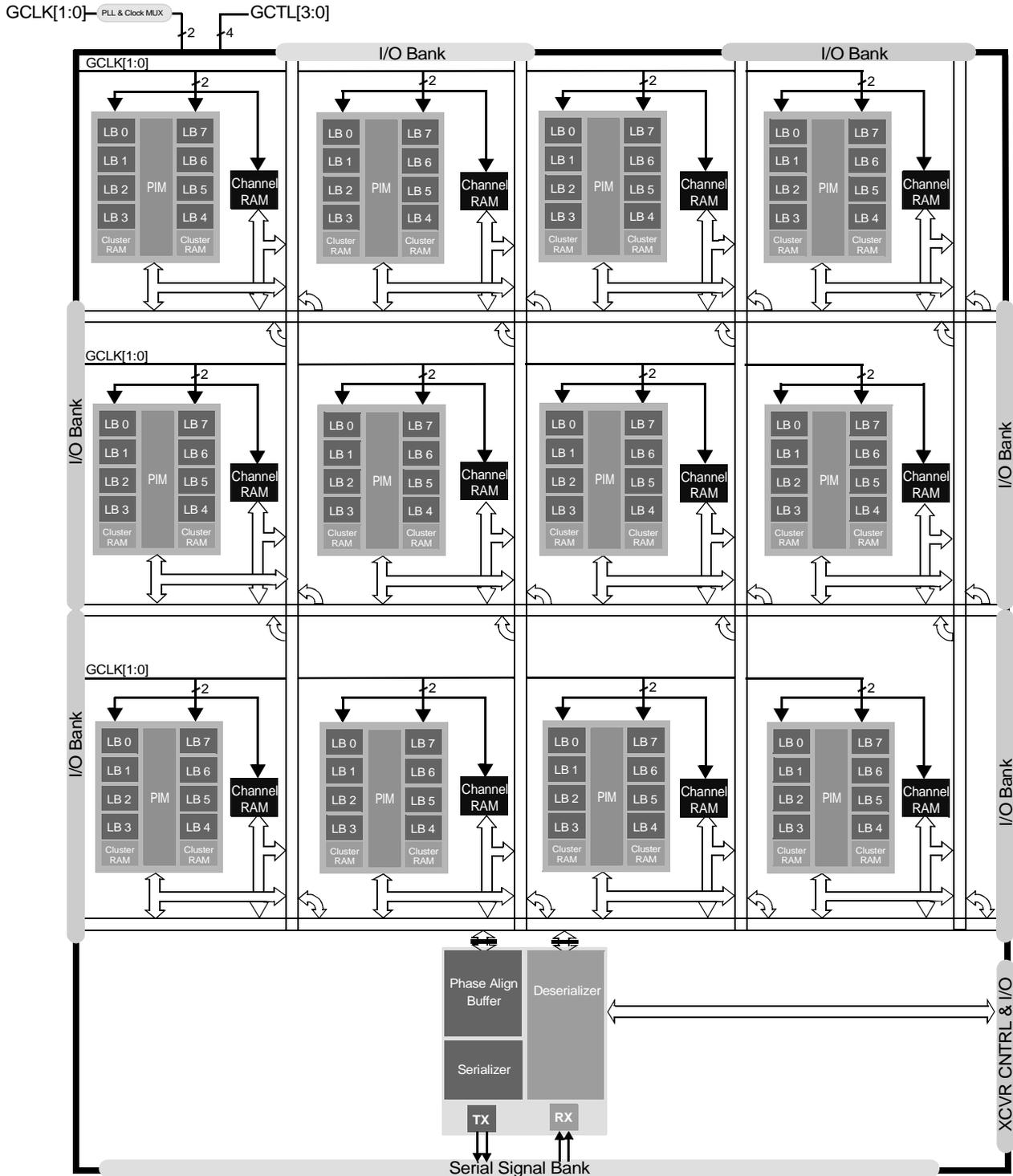


Figure 2. High-Speed PSI™ Block Diagram (25G01K100) with I/O Bank Structure.

Functional Description

The Programmable Serial Interface (PSI) family is a point-to-point or point-to-multipoint programmable communications building block allowing the manipulation and transfer of data over high-speed serial links at signaling speeds ranging from 200 Mbps to 1.5Gbps or 2.5 Gbps per serial link. The PSI family is designed to combine the high speed, predictable timing, high density, low power, and ease of use of complex programmable logic devices (CPLD) with the serializing/deserializing (SERDES) capability of high-speed serial transceivers. The family is divided into two groups: High-Speed PSI and Frequency—Agile PSI. Both groups have unique transceiver characteristics that define the specific transceiver block operation of a given PSI device.

The architecture of the device is based on logic block clusters (LBC) and serial transceiver blocks that are connected by horizontal and vertical routing channels. Each LBC features eight individual logic blocks (LB) of 16 macrocells and two cluster memory blocks. Adjacent to each LBC is a channel memory block which is externally accessible through the I/O interface. Each transmit channel of the transceiver accepts parallel characters, encodes each character for transport and converts it to serial data. Each receive channel accepts serial data and converts it to parallel data, decoding the data into characters and presents these characters to the routing channels of the PSI unit.

High-Speed PSI

The transceiver operation of the high-speed programmable serial interface devices is self-contained in a single block. It has separate transmit and receive PLLs and a Clock and Data Recovery (CDR) unit for flexible clocking. The transmit channel accepts a 16-bit input character from the routing channels and passes the character to an elasticity buffer. This character is then serialized and output on dual differential transmission-line drivers at the required bit-rate. The receive channel accepts a serial bit-stream from the two differential line receivers. This bit-stream is deserialized and a 16-bit character is presented to the routing channels in the PSI device. The block also features loop-back and loop-through modes for simplified design debugging.

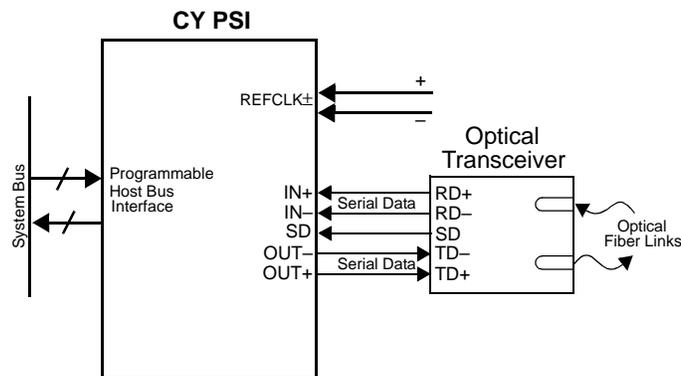


Figure 3. High-Speed PSI System Connections with an Optical Interface.

Global Routing Description

The routing architecture in the PLD block of a PSI device is made up of horizontal and vertical (H&V) routing channels. These routing channels allow signals to move among I/Os, logic blocks and memories. In addition to the horizontal and vertical routing channels that interconnect the I/O banks, channel memory blocks, transceiver blocks and logic block clusters, each LBC contains a Programmable Interconnect Matrix™ (PIM™), which is used to route signals among the logic blocks and the cluster memory blocks in the LBC.

Figure 5 is a block diagram of the routing channels that interface within the PSI architecture. The LBC is exactly the same for every member of the PSI family.

Transceiver Block

Each transceiver block of a given PSI device will have one serializer transmit path and one deserializer receive path operating at a speed from 200 Mbps to 1.5Gbps or 2.5 Gbps. The transceiver block interfaces to the routing channels of the PSI device through highly configurable datapath cells. For specific architecture and operation of the transceiver blocks please refer to the Serial Transceiver Operation section (page 17).

High-Speed PSI Transceiver Blocks

High-Speed PSI devices include one or two transceiver blocks operating at 2.5 Gbps per channel. Both channels operate independently of each other. They use the same reference clock.

The internal interfacing to the transceiver blocks of the high-speed device occur through the port definition of the high-speed transceiver block. The internal signals and their definition are described in the “Pin & Signal Description” section (page 46).

Standard Datapath Cell

Figure 4 is a block diagram of the PSI datapath cell. The datapath cell contains a three-state transmit buffer, a receive buffer, and a register that can be configured as an transmit or receive register.

The Transceiver Enable (TE) can be selected from one of the four global control signals or from one of two Output Control Channel (OCC) signals. The transmit enable can be configured as always enabled or always disabled or it can be controlled by one of the remaining inputs to the mux. The selection is done via a mux that includes V_{CC} and GND as inputs.

One of the global clocks can be selected as the clock for the datapath cell register. The clock mux output is an input to a clock polarity mux that allows the transmit/receive register to be clocked on either edge of the clock.

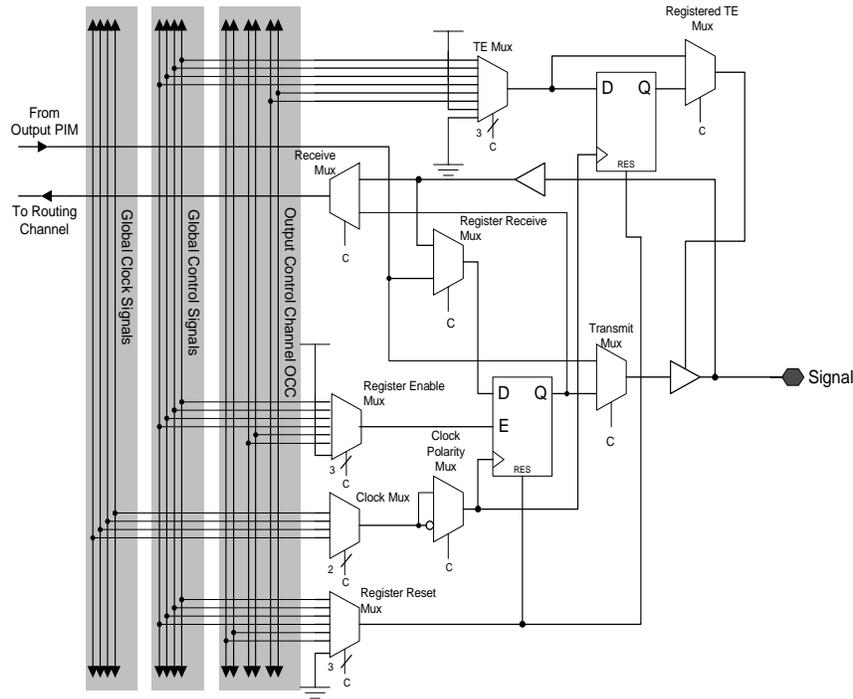


Figure 4. Block Diagram of a Standard Datapath Cell.

Logic Block Cluster (LBC)

The PSI architecture consists of several logic block clusters, each of which have 8 Logic Blocks (LB) and 2 cluster memory blocks connected via a Programmable Interconnect Matrix (PIM) as shown in *Figure 6*. Each cluster memory block consists of 8-Kbit single-port RAM, which is configurable as synchronous or asynchronous. The cluster memory blocks can be cascaded with other cluster memory blocks within the same LBC as well as other LBCs to implement larger memory func-

tions. If a cluster memory block is not specifically utilized by the designer, Cypress's *Warp* software can automatically use it to implement large blocks of logic.

All LBCs interface with each other via horizontal and vertical routing channels.

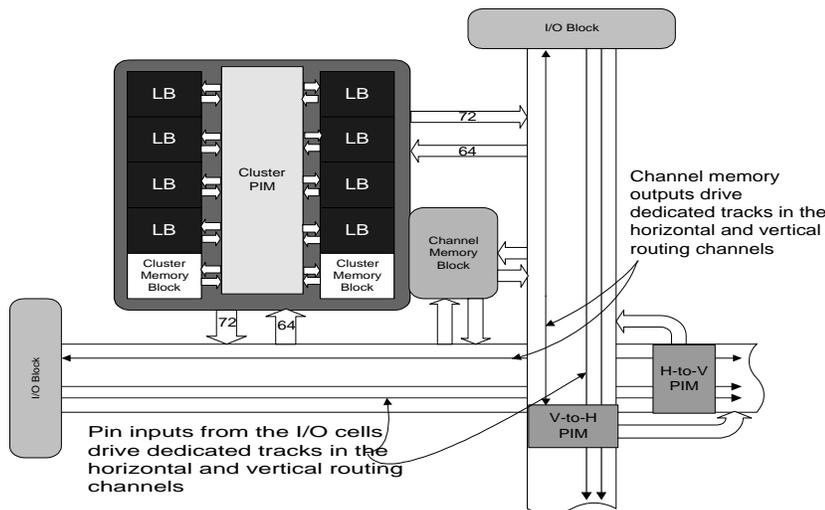


Figure 5. PSI Routing Interface.

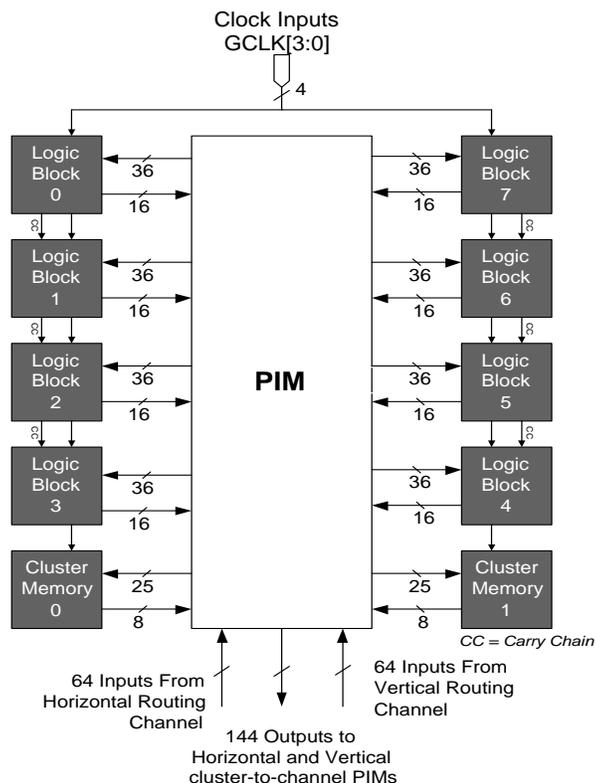


Figure 6. PSI Logic Block Cluster Diagram.

Logic Block (LB)

The logic block is the basic building block of the PSI architecture. It consists of a product term array, an intelligent product-term allocator, and 16 macrocells.

Product Term Array

Each logic block features a 72 x 83 programmable product term array. This array accepts 36 inputs from the PIM. These inputs originate from device pins and macrocell feedbacks as well as cluster memory and channel memory feedbacks. Active LOW and active HIGH versions of each of these inputs are generated to create the full 72-input field. The 83 product terms in the array can be created from any of the 72 inputs.

Of the 83 product terms, 80 are for general-purpose use for the 16 macrocells in the logic block. Two of the remaining three product terms in the logic block are used as asynchronous set and asynchronous reset product terms. The final product term is the Product Term clock (PTCLK) and is shared by all 16 macrocells within a logic block.

Product Term Allocator

Through the product term allocator, *Warp* software automatically distributes the 80 product terms as needed among the 16 macrocells in the logic block. The product term allocator pro-

vides two important capabilities without affecting performance: product term steering and product term sharing.

Product Term Steering

Product term steering is the process of assigning product terms to macrocells as needed. For example, if one macrocell requires ten product terms while another needs just three, the product term allocator will “steer” ten product terms to one macrocell and three to the other. On PSI devices, product terms are steered on an individual basis. Any number between 1 and 16 product terms can be steered to any macrocell.

Product Term Sharing

Product term sharing is the process of using the same product term among multiple macrocells. For example, if more than one function has one or more product terms in its equation that are common to other functions, those product terms are only created once. The PSI product term allocator allows sharing across groups of four macrocells in a variable fashion. The software automatically takes advantage of this capability so that the user does not have to intervene.

Note that neither product term sharing nor product term steering have any effect on the speed of the product. All steering and sharing configurations have been incorporated in the timing specifications for the PSI devices.

Macrocell

Within each logic block there are 16 macrocells. Each macrocell accepts a sum of up to 16 product terms from the product term array. The sum of these 16 product terms can be output in either registered or combinatorial mode. *Figure 7* displays the block diagram of the macrocell. The register can be asynchronously preset or asynchronously reset at the macrocell level with the separate preset and reset product terms. Each of these product terms features programmable polarity. This allows the registers to be preset or reset based on an AND expression or an OR expression.

An XOR gate in the PSI macrocell allows for many different types of equations to be realized. It can be used as a polarity mux to implement the true or complement form of an equation in the product term array or as a toggle to turn the D flip-flop into a T flip-flop. The carry-chain input mux allows additional flexibility for the implementation of different types of logic. The macrocell can utilize the carry chain logic to implement adders, subtractors, magnitude comparators, parity tree, or even generic XOR logic. The output of the macrocell is either registered or combinatorial.

Carry Chain Logic

The PSI macrocell features carry chain logic which is used for fast and efficient implementation of arithmetic operations. The carry logic connects macrocells in up to 4 logic blocks for a total of 64 macrocells. Effective data path operations are im-

plemented through the use of carry-in arithmetic, which drives through the circuit quickly. *Figure 7* shows that the carry chain logic within the macrocell consists of two product terms (CPT0 and CPT1) from the PTA and an input carry-in for carry logic. The inputs to the carry chain mux are connected directly to the product terms in the PTA. The output of the carry chain mux generates the carry-out for the next macrocell in the logic block as well as the local carry input that is connected to an input of the XOR input mux. Carry-in and a configuration bit are inputs to an AND gate. This AND gate provides a method of segmenting the carry chain in any macrocell in the logic block.

Macrocell Clocks

Clocking of the register is highly flexible. Four global synchronous clocks (GCLK[3:0]) and a Product Term clock (PTCLK) are available at each macrocell register. Furthermore, a clock polarity mux within each macrocell allows the register to be clocked on the rising or the falling edge (see macrocell diagram in *Figure 7*).

PRESET/RESET Configurations

The macrocell register can be asynchronously preset and reset using the PRESET and RESET mux. Both signals are active high and can be controlled by either of two Preset/Reset product terms (PRC[1:0] in *Figure 7*) or GND. In situations where the PRESET and RESET are active at the same time, RESET takes priority over PRESET.

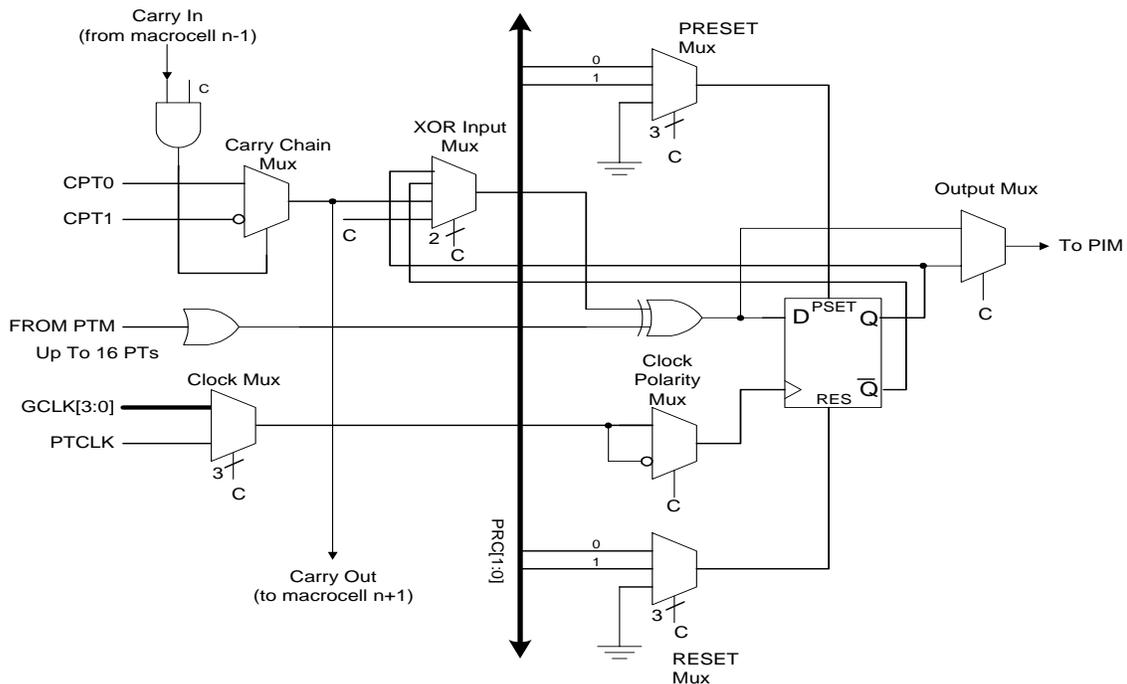


Figure 7. PSI Macrocell.

Embedded Memory

Each member of the PSI family contains two types of embedded memory blocks. The channel memory block is placed at the intersection of horizontal and vertical routing channels. Each channel memory block is 4096 bits in size and can be configured as asynchronous or synchronous Dual-Port RAM, Single-Port RAM, Read-Only memory (ROM), or synchronous FIFO memory. The memory organization is configurable as 4Kx1, 2Kx2, 1Kx4 and 512x8. The second type of memory block is located within each LBC and is referred to as a cluster memory block. Each LBC contains two cluster memory blocks that are 8192 bits in size. Similar to the channel memory blocks, the cluster memory blocks can be configured as 8Kx1, 4Kx2, 2Kx4 and 1Kx8 and can be configured as either asynchronous or synchronous Single-Port RAM or ROM.

Cluster Memory

Each logic block cluster of the PSI device contains two 8192-bit cluster memory blocks. *Figure 8* is a block diagram of the cluster memory block and the interface of the cluster memory block to the cluster PIM.

The output of the cluster memory block can be optionally registered to perform synchronous pipelining or to register asynchronous read and write operations. The output registers contain an asynchronous RESET which can be used in any type of sequential logic circuits (e.g., state machines).

There are four global clocks (GCLK[3:0]) and one local clock available for the input and the output registers. The local clock for the input registers is independent of the one used for the output registers. The local clock is generated in the user-design in a macrocell or comes from an I/O pin.

Cluster Memory Initialization

The cluster memory powers up in an undefined state, but is set to a user-defined known state during configuration. To facilitate the use of look-up-table (LUT) logic and ROM applications, the cluster memory blocks can be initialized with a given set of data when the device is configured at power up. For LUT and ROM applications, the user cannot write to memory blocks.

Channel Memory

The PSI architecture includes an embedded memory block at each crossing point of horizontal and vertical routing channels. The channel memory is a 4096-bit embedded memory block that can be configured as asynchronous or synchronous Single-Port RAM, Dual-Port RAM, ROM, or synchronous FIFO memory.

Data, address, and control inputs to the channel memory are driven from horizontal and vertical routing channels. All data and FIFO logic outputs drive dedicated tracks in the horizontal and vertical routing channels. The clocks for the channel memory block are selected from four global clocks and pin inputs from the horizontal and vertical channels. The clock muxes also include a polarity mux for each clock so that the user can choose an inverted clock.

Dual-Port (Channel Memory) Configuration

Each port has distinct address inputs, as well as separate data and control inputs that can be accessed simultaneously. The inputs to the Dual-Port memory are driven from the horizontal and vertical routing channels. The data outputs drive dedicated tracks in the routing channels. The interface to the routing is such that Port A of the Dual-Port interfaces primarily with the horizontal routing channel and Port B interfaces primarily with the vertical routing channel.

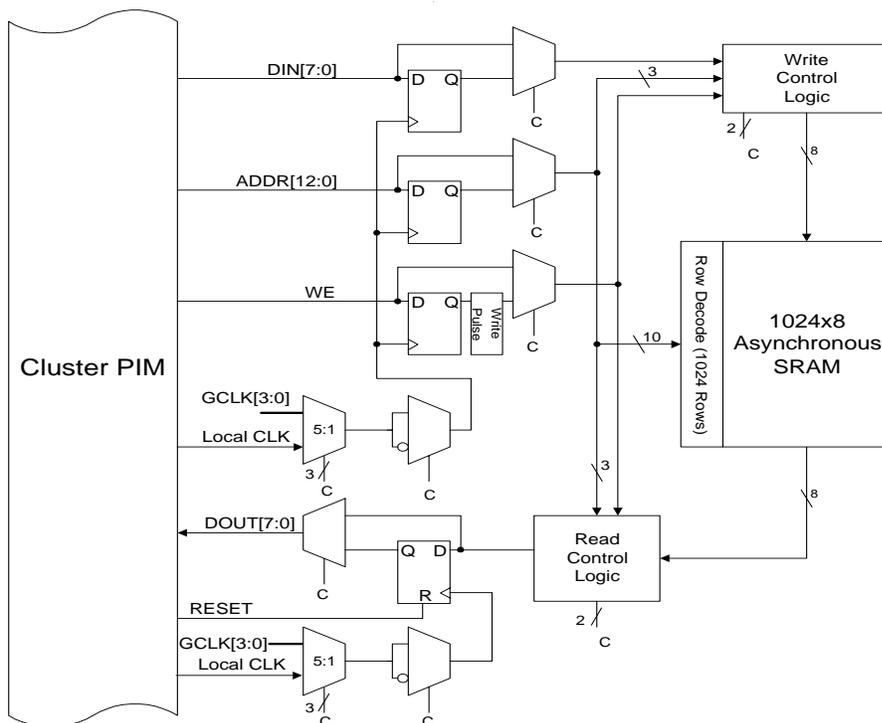


Figure 8. Block Diagram of Cluster Memory Block.

The clocks for each port of the Dual-Port configuration are selected from four global clocks and two local clocks. One local clock is sourced from the horizontal channel and the other from the vertical channel. The data outputs of the dual-port memory can also be registered. Clocks for the output registers are also selected from four global clocks and two local clocks. One clock polarity mux per port allows the use of true or complement polarity for input and output clocking purposes.

Arbitration

The Dual-Port configuration of the Channel Memory Block provides arbitration when both ports access the same address at the same time. Depending on the memory operation being attempted, one port always gets priority. See *Table 1* for details on which port gets priority for read and write operations. An active-LOW 'Address Match' signal is generated when an address collision occurs.

Table 1. Arbitration Result: Address Match Signal Becomes Active

Port A	Port B	Result of Arbitration	Comment
Read	Read	No arbitration required	Both ports read at the same time
Write	Read	Port A gets priority	If Port B requests first then it will read the current data. The output will then change to the newly written data by Port A
Read	Write	Port B gets priority	If Port A requests first then it will read the current data. The output will then change to the newly written data by Port B
Write	Write	Port A gets priority	Port B is blocked until Port A is finished writing

FIFO (Channel Memory) Configuration

The channel memory blocks are also configurable as synchronous FIFO RAM. In the FIFO mode of operation, the channel memory block supports all normal FIFO operations without the use of any general-purpose logic resources in the device.

The FIFO block contains all of the necessary FIFO flag logic, including the read and write address pointers. The FIFO flags include an empty/full flag (EF), half-full flag (HF), and programmable almost-empty/full (PAEF) flag output. The FIFO configuration has the ability to perform simultaneous read and write operations using two separate clocks. These clocks may be tied together for a single operation or may run independently for asynchronous read/write (w.r.t. each other) applications. The data and control inputs to the FIFO block are driven from the horizontal or vertical routing channels. The data and flag outputs are driven onto dedicated routing tracks in both the

horizontal and vertical routing channels. This allows the FIFO blocks to be expanded by using multiple FIFO blocks on the same horizontal or vertical routing channel without any speed penalty.

In FIFO mode, the write and read ports are controlled by separate clock and enable signals. The clocks for each port are selected from four global clocks and two local clocks.

One local clock is sourced from the horizontal channel and the other from the vertical channel. The data outputs from the read port of the FIFO can also be registered. One clock polarity mux per port allows using true or complement polarity for read and write operations. The write operation is controlled by the clock and the write enable pin. The read operation is controlled by the clock and the read enable pin. The enable pins can be sourced from horizontal or vertical channels.

Channel Memory Initialization

The channel memory powers up in an undefined state, but is set to a user-defined known state during configuration. To facilitate the use LUT logic and ROM applications, the channel memory blocks can be initialized with a given set of data when the device is configured at power up. For LUT and ROM applications, the user cannot write to memory blocks.

Channel Memory Routing Interface

Similar to LBC outputs, the channel memory blocks feature dedicated tracks in the horizontal and vertical routing channels for the data outputs and the flag outputs, as shown in *Figure 9*. This allows the channel memory blocks to be expanded easily. These dedicated lines can be routed to I/O pins as chip outputs or to other logic block clusters to be used in logic equations.

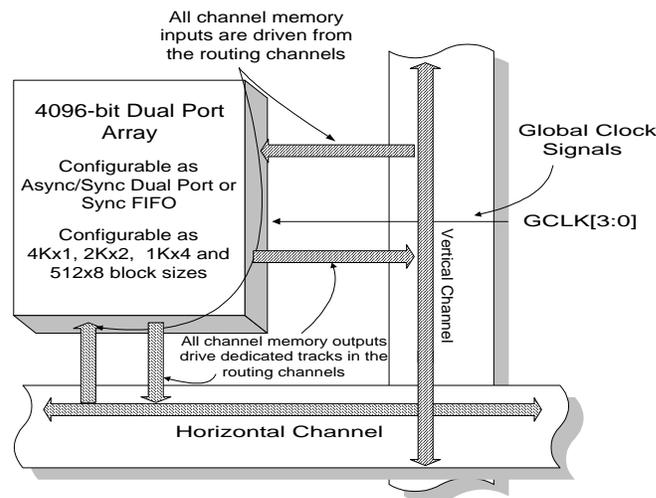


Figure 9. Block Diagram of Channel Memory Block.

I/O Banks

The PSI interfaces the horizontal and vertical routing channels to the pins through I/O banks. There are several I/O banks per device as shown in *Figure 10* and all I/Os from an I/O bank are located in the same section of a package for PCB layout convenience. There exist two kinds of I/O banks; fixed-signal I/O banks and user programmable I/O banks.

The first fixed signal bank is the Serial Signal Bank. This bank includes all differential serial data transmission and receive signals. The second bank is the Transceiver Control Bank. This bank includes all static signal pins required for the configuration and operation of the transceiver blocks in each of the PSI devices.

Each PSI device has several types of user programmable I/O banks. The table on the following page indicates the availability of each type of programmable bank by device. Supported I/O standards for each bank are addressed by the appropriate V_{REF} and V_{CCIO} voltages. All the V_{REF} and V_{CCIO} pins in an I/O bank must be connected to the same V_{REF} and V_{CCIO} voltage respectively. This requirement restricts the number of I/O standards supported by an I/O bank at any given time. It also dictates the I/O standard used for the GCTL[3:0] pins.

The architecture defining each programmable I/O bank consists of several I/O cells, where each I/O cell contains an input/output register, an output enable register, programmable slew rate control and programmable bus hold control logic. Each I/O cell drives a pin output of the device; the cell also supplies an input to the device that connects to a dedicated track in the associated routing channel.

There are four dedicated inputs (GCTL[3:0]) that are used as Global Control Signals available to every I/O cell. These global control signals may be used as output enables, register resets and register clock enables as shown in *Figure 11*.

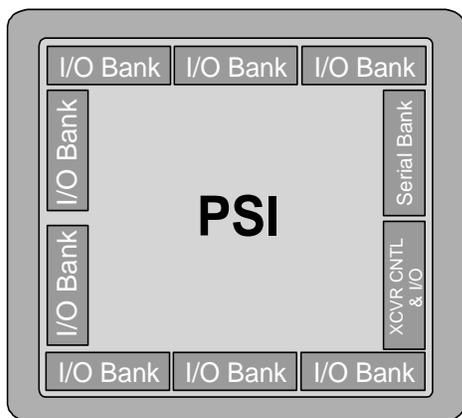


Figure 10. PSI I/O Bank Block Diagram.

PSI Programmable I/O Banks

Device	Flexible	Semi-Flexible	Specific	
			V_{CCIO}	V_{REF}
25G01K100	Bank[0:3, 5]	Bank[4] $V_{CCIO}=3.3V$	Bank[6:7]	
			1.5V	0.68-0.90V
25G02K100	Bank[0:3]	Bank[4] $V_{CCIO}=3.3V$	Bank[5:7]	
			1.5V	0.68-0.90V

IO Standards

I/O Standard	V_{REF} (V)		V_{CCIO}	Termination Voltage (V_{TT})
	Min	Max		
LVTTTL	N/A		3.3 V	N/A
LVC MOS	N/A		3.3 V	N/A
LVC MOS3	N/A		3.0 V	N/A
LVC MOS2	N/A		2.5 V	N/A
LVC MOS18	N/A		1.8 V	N/A
3.3V PCI	N/A		3.3 V	N/A
GTL+	0.9	1.1	N/A	1.5
SSTL3 I	1.3	1.7	3.3 V	1.5
SSTL3 II	1.3	1.7	3.3 V	1.5
SSTL2 I	1.15	1.35	2.5 V	1.25
SSTL2 II	1.15	1.35	2.5 V	1.25
HSTL I	0.68	0.9	1.5 V	0.75
HSTL II	0.68	0.9	1.5 V	0.75
HSTL III	0.68	0.9	1.5 V	1.5
HSTL IV	0.68	0.9	1.5 V	1.5

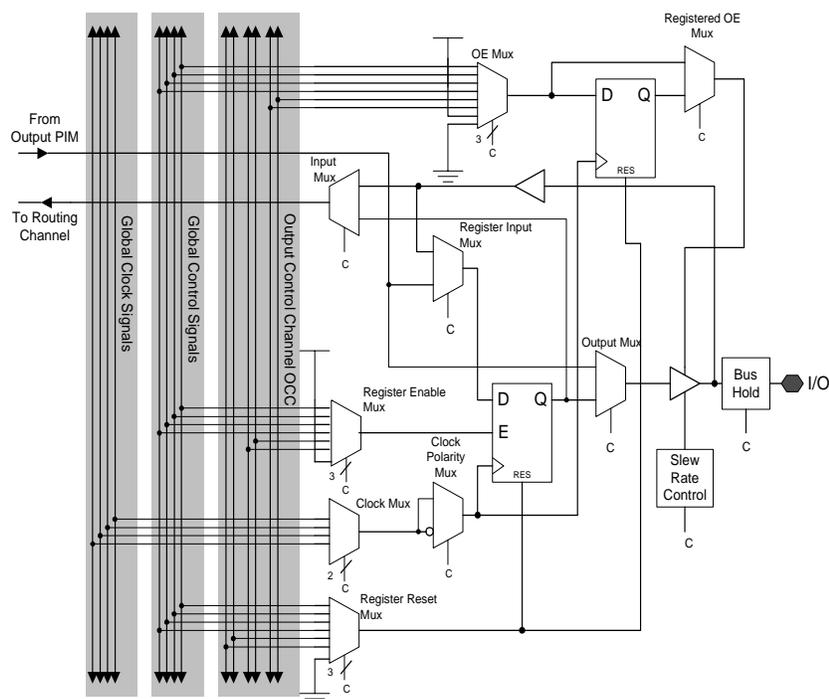


Figure 11. Block Diagram of I/O Cell.

I/O Cell

Figure 11 is a block diagram of the PSI I/O cell. The I/O cell contains a three-state input buffer, an output buffer, and a register that can be configured as an input or output register. The output buffer has a slew rate control option that can be used to configure the output for a slower slew rate. The input of the device and the pin output can each be configured as registered or combinatorial, however only one path can be configured as registered in a given design.

The output enable can be selected from one of the four global control signals or from one of two Output Control Channel (OCC) signals. The output enable can be configured as always enabled or always disabled or it can be controlled by one of the remaining inputs to the mux. The selection is done via a mux that includes V_{CC} and GND as inputs.

One of the global clocks can be selected as the clock for the I/O cell register. The clock mux output is an input to a clock polarity mux that allows the input/output register to be clocked on either edge of the clock.

Slew Rate Control

The output buffer has a slew rate control option. This allows the output buffer to slew at a fast rate (3 V/ns) or a slow rate (1 V/ns). All I/Os default to fast slew rate. For designs concerned with meeting FCC emissions standards the slow edge provides for lower system noise. For designs requiring very high performance the fast edge rate provides maximum system performance.

Programmable Bus Hold

On each I/O pin, user-programmable bus-hold is included. Bus-hold, which is an improved version of the popular internal

pull-up resistor, is a weak latch connected to the pin that does not degrade the device's performance. As a latch, bus-hold maintains the last state of a pin when the pin is placed in a high-impedance state, thus reducing system noise in bus-interface applications. Bus-hold additionally allows unused device pins to remain unconnected on the board, which is particularly useful during prototyping as designers can route new signals to the device without cutting trace connections to V_{CC} or GND. For more information, see the application note "Understanding Bus-Hold – A Feature of Cypress CPLDs."

Clocks

PSI has four primary global clock trees in the CPLD portion of the device (INTCLK[3:0]). Each of these clock trees distributes a clock signal to every cluster, channel memory, and I/O cell in the CPLD. The global clock trees are designed such that the clock skew is minimized while maintaining an acceptable clock delay. Each of the INTCLKs can choose from two input sources for the clock signal: A PLL derived output or another one as shown in the table below:

Device	IN-TCLK[0]	IN-TCLK[1]	IN-TCLK[2]	IN-TCLK[3]
25G01K100	GCLK[0]	GCLK[1]	TXCLK	RXCLK
25G02K100	GCLK[0]	RXCLK	TXCLK	RXCLK_B

GCLK[0] and GCLK[1] are accessible through pins on the device package. TXCLK and RXCLK are provided internally to the device. TXCLK (transmit clock) is intended for data transfer from the CPLD block to the transmit channel of the transceiver block. RXCLK (receive clock) is intended for data transfer from the receive channel of the transceiver block to the CPLD block. The TXCLK and RXCLK can also be used for

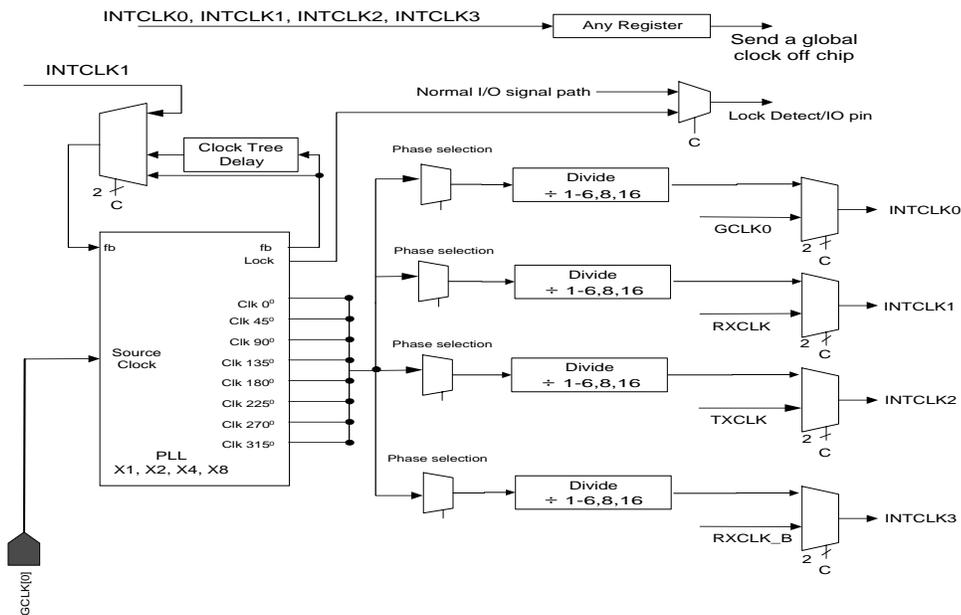


Figure 13. Block Diagram of Spread Aware PLL for CYP25G02K100.

Table 2. PLL Multiply and Divide Options—without INTCLK1 Feedback

Input Frequency (GCLK[0]) f_{PLLI} (MHz)	Valid Multiply Options		Valid Divide Options		
	Value	VCO Output Frequency (MHz)	Value	Output Frequency (INTCLK[3:0]) f_{PLLO} (MHz)	Off-Chip Clock Frequency
12.5–25	8	100–200	1–6, 8, 16	6.25–200	3.12–100
25–33	8	200–266	1–6, 8, 16	12.5–266	6.25–133
	4	100–133	1–6, 8, 16	6.25–133	3.12–66
33–50	4	133–200	1–6, 8, 16	8.33–200	4.16–100
50–66	4	200–266	1–6, 8, 16	12.5–266	6.25–133
	2	100–133	1–6, 8, 16	6.25–133	3.12–66
66–100	2	133–200	1–6, 8, 16	8.3–200	4.16–100
100–133	2	200–266	1–6, 8, 16	12.5–266	6.25–133
	1	100–133	1–6, 8, 16	6.25–133	3.12–66

Table 3. PLL Multiply and Divide Options—with External Feedback

Input (GCLK) Frequency f_{PLLI} (MHz)	Valid Multiply Options		Valid Divide Options		
	Value	VCO Output Frequency (MHz)	Value	Output (INTCLK) Frequency f_{PLLO} (MHz)	Off-Chip Clock Frequency
50–66	1	100–133	1	100–133	50–66
66–100	1	133–200	1	133–200	66–100
100–133	1	200–266	1	200–266	100–133



Table 4 describes the valid phase shift options that can be used with or without an external feedback.

**Table 4. PLL Phase Shift Options—
with and without INTCLK1 Feedback**

Without External Feedback	With External Feedback
0°, 45°, 90°, 135°, 180°, 225°, 270°, 315°	0°

Table 5 is an example of the effect of all the available divide and phase shift options on a VCO output of 250 MHz. It also shows the effect of division on the duty cycle of the resultant clock. Note that the duty cycle is 50-50 when a VCO output is divided by an even number. Also note that the phase shift applies to VCO output and not to the divided output

For more details on the architecture and operation of this PLL please refer to the application note entitled "PSI PLL and Clock Tree."

Table 5. Timing of Clock Phases for all Divide Options for a VCO Output Frequency of 250 MHz

Divide Factor	Period (ns)	Duty Cycle%	0° (ns)	45° (ns)	90° (ns)	135° (ns)	180° (ns)	225° (ns)	270° (ns)	315° (ns)
1	4	40-60	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
2	8	50	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
3	12	33-67	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
4	16	50	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
5	20	40-60	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
6	24	50	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
8	32	50	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5
16	64	50	0	0.5	1.0	1.5	2.0	2.5	3.0	3.5

Timing Model

One important feature of the PSI family is the simplicity of its timing. All combinatorial and registered/synchronous delays are worst case and system performance is static (as shown in the AC specs section) as long as data is routed through the same horizontal and vertical channels. *Figure 14* illustrates the true timing model for the 200-MHz devices. For synchronous clocking of macrocells, a delay is incurred from macrocell clock to macrocell clock of separate Logic Blocks within the same cluster, as well as separate Logic Blocks within different clusters. This is shown as t_{SCS} and t_{SCS2} in *Figure 14*. For combinatorial paths, any input to any output (from corner to corner on the device), incurs a worst-case delay in the 100K gate PSI regardless of the amount of logic or which horizontal and vertical channels are used. This is the t_{PD} shown in *Figure*

14. For synchronous systems, the input set-up time to the output macrocell register and the clock to output time are shown as the parameters t_{MCS} and t_{MCCO} shown in the *Figure 14*. These measurements are for any output and synchronous clock, regardless of the logic placement.

PSI features:

- no dedicated vs. I/O pin delays
- no penalty for using 0–16 product terms
- no added delay for steering product terms
- no added delay for sharing product terms
- no output bypass delays

The simple timing model of the PSI family eliminates unexpected performance penalties.

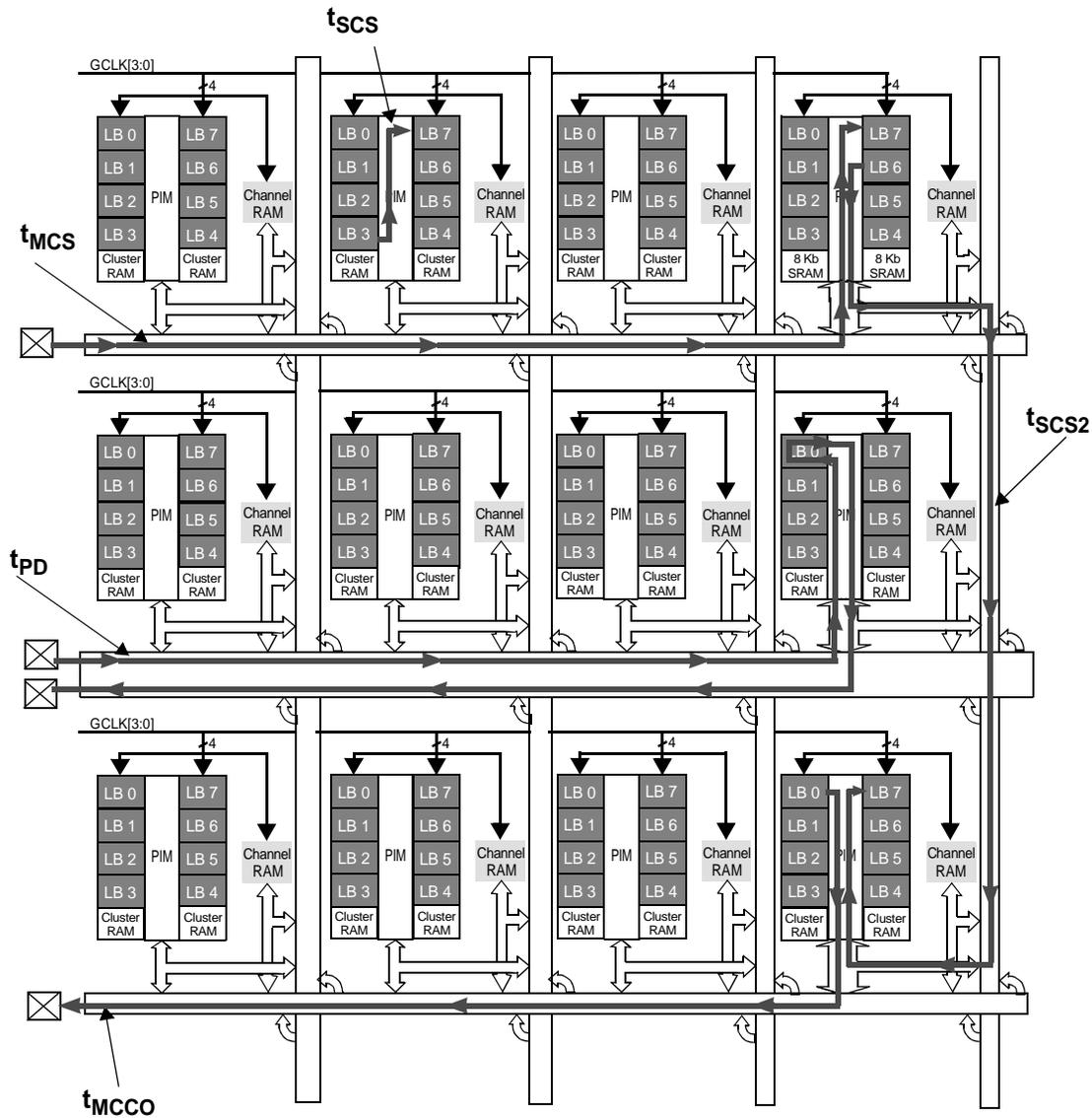


Figure 14. Timing Model for 100K gate PSI Devices.

Serial Transceiver Operation

The PSI transceiver block is a highly configurable transceiver designed to support reliable transfer of large quantities of data, using high-speed serial links, from one or multiple sources to one or multiple destinations. This block supports either a single 16-bit wide channel in the case of High-Speed PSI devices or four single-byte or single-character channels, that may be combined to support transfer of wider buses, in the case of Frequency Agile PSI devices.

High-Speed PSI Transceiver Operation

Transmit Data Path

Operating Modes

The transmit path of the High-Speed PSI supports 16-bit-wide data paths.

Phase-Align Buffer

Data from the input register is passed to a phase-align buffer (FIFO). This buffer is used to absorb clock phase differences between the transmit input clock and the internal character clock.

Initialization of the phase-align buffer takes place when the FIFO_RST signal is asserted LOW. When FIFO_RST is returned HIGH, the present input clock phase relative to TXCLK is set. Once set, the input clock is allowed to skew in time up to half a character period in either direction relative to REFCLK; i.e. ± 180 . This time shift allows the delay path of the character clock (relative to REFCLK) to change due to operating voltage and temperature while not effecting the desired operation. FIFO_RST is an asynchronous signal. FIFO_ERR is the transmit FIFO Error indicator. When HIGH, the transmit FIFO has either under or overflowed. The FIFO can be externally reset or logically reset by PSI logic to clear the error indication or if no action is taken, the internal clearing mechanism will clear the FIFO in 9 clock cycles. When the FIFO is being reset, the output data is 1010.

Transmit PLL Clock Multiplier

The Transmit PLL Clock Multiplier accepts a 156.25-MHz external clock at the REFCLK input, and multiplies that clock by 16 to generate a bit-rate clock for use by the transmit shifter. The operating serial signaling rate and allowable range of REFCLK frequencies are listed in the High-Speed PSI Transceiver Timing Parameter Values table under "REFCLK Timing Parameters" (see page 33). The REFCLK \pm input is a standard LVPECL input.

Serializer

The parallel data from the phase-align buffer is passed to the Serializer which converts the parallel data to serial data using the bit-rate clock generated by the Transmit PLL clock multiplier. TXD[15] is the most significant bit of the output word, and is transmitted first on the serial interface.

Serial Output Driver

The serial interface Output Driver makes use of high-performance differential CML (Current Mode Logic) to provide a source-matched driver for the transmission lines. This driver receives its data from the Transmit Shifters or the receive loop-back data. The outputs have signal swings equivalent to that

of standard LVPECL drivers, and are capable of driving AC-coupled optical modules or transmission lines.

Receive Data Path

Serial Line Receivers

A differential line receiver, IN \pm , is available for accepting the input serial data stream. The serial line receiver inputs can accommodate high wire interconnect and filtering losses or transmission line attenuation ($V_{DIF} \geq 25$ mV, or 50 mV peak-to-peak differential), and can be AC-coupled to +3.3V or +5V powered fiber-optic interface modules. The common-mode tolerance of these line receivers accommodates a wide range of signal termination voltages.

Lock to Data Control

Line Receiver routed to the clock and data recovery PLL is monitored for

- status of signal detect (SD) pin
- status of LOCKREF pin
- received data stream outside normal frequency range (± 200 ppm)

This status is presented on the $\overline{\text{LFI}}$ (Line Fault Indicator) output signal, which changes asynchronously in the cases when SD or LOCKREF goes from HIGH to LOW. Otherwise, it changes synchronously to the REFCLK.

Clock/Data Recovery

The extraction of a bit-rate clock and recovery of data bits from received serial stream is performed by a Clock/Data Recovery (CDR) block. The clock extraction function is performed by high-performance embedded phase-locked loop (PLL) that tracks the frequency of the incoming bit stream and aligns the phase of the internal bit-rate clock to the transitions in the selected serial data stream.

CDR accepts a character-rate (bit-rate \div 16) reference clock on the REFCLK input. This REFCLK input is used to ensure that the VCO (within the CDR) is operating at the correct frequency (rather than some harmonic of the bit-rate), to improve PLL acquisition time, and to limit unlocked frequency excursions of the CDR VCO when no data is present at the serial inputs.

Regardless of the type of signal present, the CDR will attempt to recover a data stream from it. If the frequency of the recovered data stream is outside the limits set by the range controls, the CDR PLL will track REFCLK instead of the data stream. When the frequency of the selected data stream returns to a valid frequency, the CDR PLL is allowed to track the received data stream. The frequency of REFCLK is required to be within ± 200 ppm of the frequency of the clock that drives the REFCLK signal of the remote transmitter to ensure a lock to the incoming data stream.

For systems using multiple or redundant connections, the $\overline{\text{LFI}}$ output can be used to select an alternate data stream. When an LFI indication is detected, PSI logic can toggle selection of the input device. When such a port switch takes place, it is necessary for the PLL to re-acquire lock to the new serial stream.

External Filter

The CDR circuit uses external capacitors for the PLL filter. A 0.1- μ F capacitor needs be connected between RXCN1 and

RXCP1. Similarly a 0.1- μ F capacitor needs to be connected between RXCN2 and RXCP2. The recommended packages and dielectric material for these capacitors are 0805 X7R or 0603 X7R.

Deserializer

The CDR circuit extracts bits from the serial data stream and clocks these bits into the Deserializer at the bit-clock rate. The Deserializer converts serial data into parallel data. RXD[15] is the most significant bit of the output word and is received first on the serial interface.

Loopback/Timing Modes

High-Speed PSI supports various loopback modes as described below.

Facility Loopback (Line Loopback With Retiming)

When the LINELOOP signal is set HIGH, the Facility Loopback mode is activated and the high-speed serial receive data (IN \pm) is presented to the high-speed transmit output (OUT \pm) after retiming. In Facility Loopback mode, the high-speed receive data (IN \pm) is also converted to parallel data and presented to the low-speed receive data output pins (RXD[15:0]). The receive recovered clock is also divided down and presented to the low speed clock output (RXCLK).

Equipment Loopback (Diagnostic Loopback With Retiming)

When the DIAGLOOP signal is set HIGH, transmit data is looped back to the RX PLL, replacing IN \pm . Data is looped back

from the parallel TX inputs to the parallel RX outputs. The data is looped back at the internal serial interface and goes through transmit shifter and the receive CDR. SD is ignored in this mode.

Line Loopback Mode (Non-retimed Data)

When the LOOPA signal is set HIGH, the RX serial data is directly buffered out to the transmit serial data. The data at the serial output is not retimed.

Loop Timing Mode

When the LOOPTIME signal is set HIGH, the TX PLL is bypassed and receive bit-rate clock is used for transmit side shifter.

Reset Modes

ALL logic circuits in the device can be reset using RESET and FIFO_RST signals. When RESET is set LOW, all logic circuits except FIFO are internally reset. When FIFO_RST is set LOW, the FIFO logic is reset.

Power-down Mode

High-Speed PSI transceiver blocks provide a global power-down signal PWRDN. When LOW, this signal powers down the entire device to a minimal power dissipation state. RESET and FIFO_RST signals should be asserted LOW along with PWRDN signal to ensure low power dissipation.

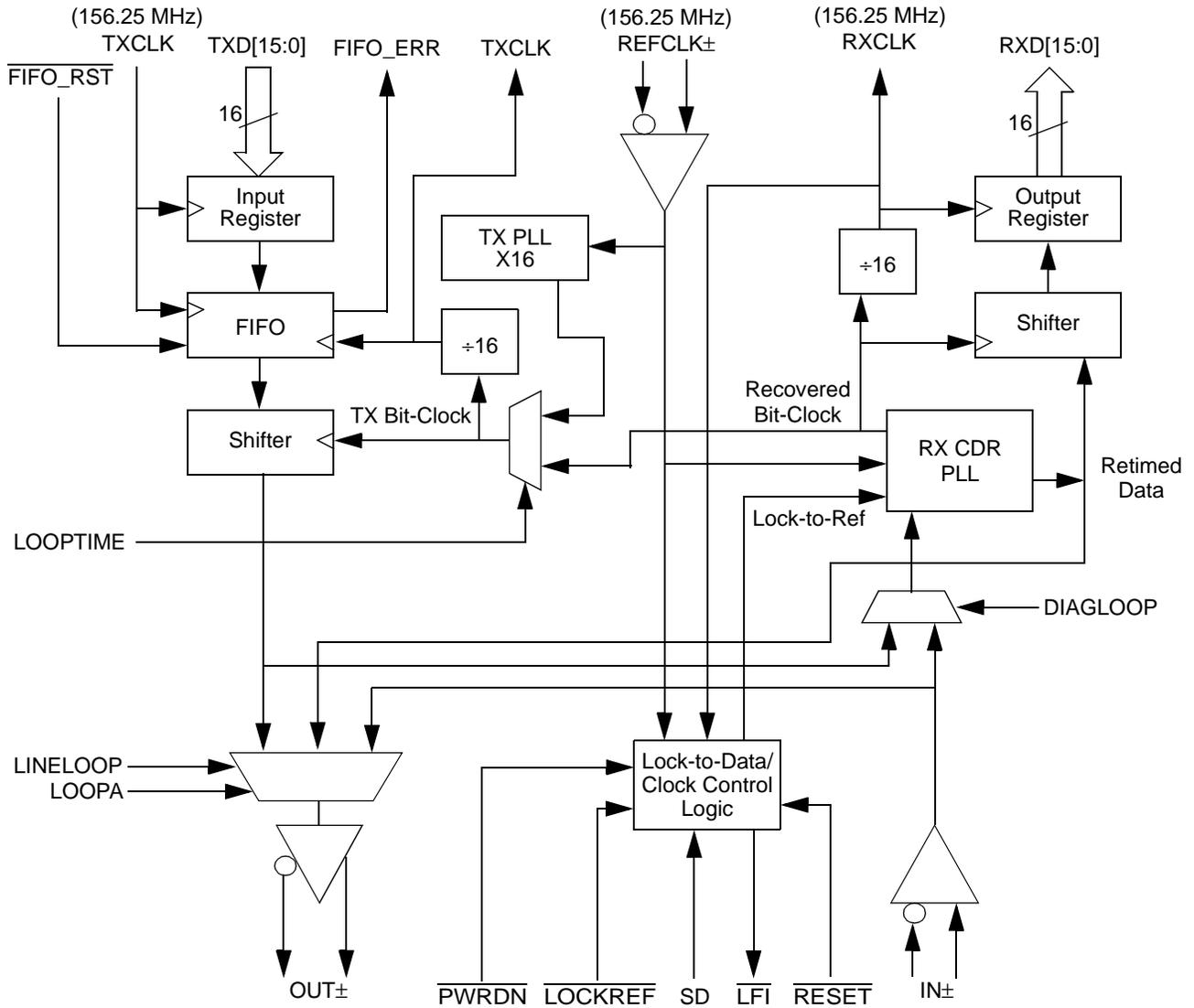


Figure 15. High Speed-PSI Transceiver Logic Block Diagram.

IEEE 1149.1 Compliant JTAG Operation

The PSI family has an IEEE std 1149.1 JTAG interface for both Boundary Scan and ISR operations.

Four dedicated pins are reserved on each device for use by the Test Access Port (TAP).

Boundary Scan

The PSI family supports Bypass, Sample/Preload, Extest, In-test, Idcode and Usercode boundary scan instructions. The JTAG interface is shown in *Figure 16*.

Frequency Agile devices also allow system level diagnosis of transceiver interface and interconnect. Boundary scan is supported on the LVCMOS signals, inputs and outputs. The high-speed serial inputs are not part of the JTAG test chain.

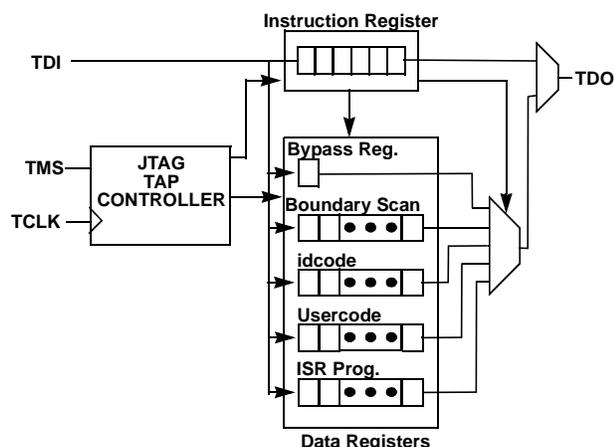


Figure 16. JTAG Interface.

In-System Reprogramming™ (ISR™)

In-System Reprogramming is the combination of the capability to program or reprogram a device on-board, and the ability to support design changes without changing the system timing or device pinout. This combination means design changes during debug or field upgrades do not cause board respins. The PSI family implements ISR by providing a JTAG compliant interface for on-board programming, robust routing resources for pinout flexibility, and a simple timing model for consistent system performance.

Configuration

The CPLD block in each device of the PSI family is designed with Self-Boot capability. An embedded on-chip EEPROM is used to store configuration data. For PSI devices, programming is defined as the loading of a user's design into the internal EEPROM. Configuration, on the other hand, is defined as the loading of a user's design into the volatile CPLD block.

Configuration can begin in two ways. It can be initiated by toggling the *Reconfig* pin from LOW to HIGH, or by issuing the appropriate IEEE std 1149.1 JTAG instruction to the PSI device via the JTAG interface. There are two IEEE std 1149.1 JTAG instructions that initiate configuration of the PSI. The *Self Config* instruction causes the PSI to (re)configure with data store in the internal EEPROM. The *Load Config* instruction causes the PSI to (re)configure with data provided by other sources such as a PC, Automatic Test Equipment (ATE), or an embedded micro-controller/processor via the JTAG port.

There are multiple configuration options available for issuing the IEEE std 1149.1 JTAG instructions to the PSI. The first method is to use a PC with the C3 ISR programming cable and software. With this method, the ISR pins of the PSI devices in the system are routed to a connector at the edge of the printed circuit board. The C3 ISR programming cable is then connected between the PC and this connector. A simple configuration file instructs the ISR software of the programming operations to be performed on the PSI devices in the system. The ISR software then automatically completes all of the necessary data manipulations required to accomplish configuration, reading, verifying, and other ISR functions. For more information on the Cypress ISR interface, see the Programming/ISR application notes at <http://www.cypress.com/pld/pldapp-notes.html>.

For systems with embedded controllers/processors, a controller/processor may be used to configure the PSI. The PSI ISR software assists in this method by converting the device HEX file into the ISR serial stream that contains the ISR instruction information and the addresses and data of locations to be configured. The controller/processor then simply directs this ISR stream to the chain of PSI devices to complete the desired reconfiguration or diagnostic operations. Contact your local sales office for information on availability of this option.

Programming

The on-chip EEPROM device of the CPLD block is programmed by issuing the appropriate IEEE std 1149.1 JTAG instruction. This can be done automatically using ISR/STAPL software. The configuration bits are sent from a PC through the JTAG port into the PSI via the C3 ISR programming cable. The data is then passed to the internal EEPROM through the Non-Volatile (NV) port of the CPLD block. For more information on how to program the PSI through ISR/STAPL, please refer to the ISR/STAPL User Guide.

Third-Party Programmers

Cypress support is available on a wide variety of third-party programmers. All major programmers (including BP Micro, System General, Hi-Lo) support the PSI family.

Development Software Support

Warp®

Warp is a state-of-the-art design environment for designing with Cypress programmable logic. *Warp* utilizes a subset of IEEE 1076/1164 VHDL and IEEE 1364 as the Hardware Description Language (HDL) for design entry. *Warp* accepts VHDL or Verilog input, synthesizes and optimizes the entered design, and outputs a configuration bitstream for the desired Delta39K device. For simulation, *Warp* provides a graphical waveform simulator as well as VHDL and Verilog Timing Models.

VHDL and Verilog are open, powerful, non-proprietary Hardware Description Languages (HDLs) that are standards for behavioral design entry and simulation. HDL allows designers to learn a single language that is useful for all facets of the design process.

Third-Party Software

Cypress products are supported in a number of third-party design entry and simulation tools. Refer to the third-party software data sheet or contact your local sales office for a list of currently supported third party vendors.



Programmable Serial Interface (High Speed Devices)

PRELIMINARY

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature-65°C to +150°C
 Soldering Temperature.....220°C
 Ambient Temperature with
 Power Applied.....-40°C to +85°C
 Junction Temperature.....135°C
 V_{CC} relative to Ground Potential -0.5V to 4.2V
 V_{CCIO} relative to Ground Potential..... -0.5V to 4.6V
 DC Voltage Applied to Outputs in High Z State -0.5V to 4.5V

Output Current into LVCMOS Outputs (LOW)..... 30 mA
 DC Input voltage.....-0.5V to 4.5V
 DC Current into Outputs.....± 20 mA^[4]
 Static Discharge Voltage.....> 2001V
 (per MIL-STD-883, Method 3015)
 Latch-Up Current.....> 200 mA

Operating Range

Range	Ambient Temperature	V_{CC}	V_{DDQ}
Commercial	0°C to +70°C	3.3V ± 10%	1.4V to 1.6V

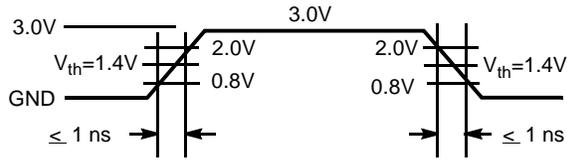
Operating Range

Range	Ambient Temperature	Junction Temperature	Output Condition	V_{CCIO}	V_{CC}	V_{CCJTAG}/V_{CCCNFG}	V_{CCPLL}	V_{CEP}
Commercial	0°C to +70°C	0°C to +85°C	3.3V	3.3V ± 0.3V	3.3V ± 0.3V	Same as V_{CCIO}	Same as V_{CC}	3.3V ± 0.3V
			2.5V	2.5V ± 0.2V				
			1.8V	1.8V ± 0.15V				
			1.5V	1.5V ± 0.1V				

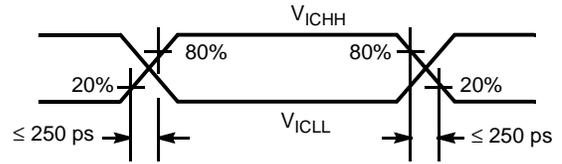
Notes:

4. DC current into outputs is 36 mA with HSTL III and 48 mA with HSTL IV.

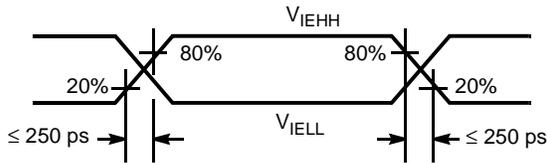
AC Test Loads and Waveforms to High-Speed PSI Transceiver Block



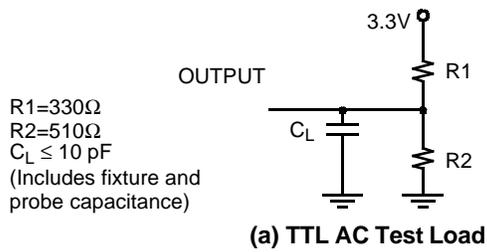
(a) LVTTTL Input Test Waveform



(b) CML Input Test Waveform



(c) LVPECL Input Test Waveform



(a) TTL AC Test Load



(b) CML AC Test Load

Electrical Characteristics Over the Operating Range

DC Characteristics

Parameter	Description	Test Conditions	V _{CCIO} = 3.3V		V _{CCIO} = 2.5V		V _{CCIO} = 1.8V		Unit
			Min.	Max.	Min.	Max.	Min.	Max.	
V _{DRINT}	Data Retention V _{CC} Voltage (config data may be lost below this)		1.5		1.5		1.5		V
V _{DRIO}	Data Retention V _{CCIO} Voltage (config data may be lost below this)		1.2		1.2		1.2		V
I _{IX}	Input Leakage Current	GND ≤ V _I ≤ 3.6V	-10	10	-10	10	-10	10	μA
I _{OZ}	Output Leakage Current	GND ≤ V _O ≤ V _{CCIO}	-10	10	-10	10	-10	10	μA
I _{OS} ^[5]	Output Short Circuit Current	V _{CCIO} = Max., V _{OUT} = 0.5V		-160		-160		-160	mA
I _{BHL}	Input Bus Hold LOW Sustaining Current	V _{CC} = Min., V _{PIN} = V _{IL}	+40		+30		+25		μA
I _{BHH}	Input Bus Hold HIGH Sustaining Current	V _{CC} = Min., V _{PIN} = V _{IH}	-40		-30		-25		μA
I _{BHLO}	Input Bus Hold LOW Overdrive Current	V _{CC} = Max.		+250		+200		+150	μA
I _{BHHO}	Input Bus Hold HIGH Overdrive Current	V _{CC} = Max.		-250		-200		-150	μA

Capacitance

Parameter	Description	Test Conditions	Min.	Max.	Unit
C _{I/O}	Input/Output Capacitance	V _{in} = V _{CCIO} @ f = 1 MHz 25°C		10	pF
C _{PCI}	PCI compliant I/O Capacitance	V _{in} = V _{CCIO} @ f = 1 MHz 25°C		8	pF
C _{CLK}	Clock Signal Capacitance	V _{in} = V _{CCIO} @ f = 1 MHz 25°C	5	12	pF
C _{INPECL}	PECL Input Capacitance	V _{CC} = 3.3V @ f = 1 MHz 25°C		4	pF
C _{SD1}	SD Pin Input Capacitance	V _{CC} = 3.3V @ f = 1 MHz 25°C		5	pF
C _{INC1}	CML Input Capacitance	V _{CC} = 3.3V @ f = 1 MHz 25°C		4	pF

DC Specifications - Power

Parameter	Device	Description	Test Conditions	Standby	Typical	Unit
I _{CC2} ^[6]	25G01K100	Active Power Supply Current	Frequency = Max Commercial	16	800	mA
	25G02K100	Active Power Supply Current	Frequency = Max Commercial	22	1200	mA

Notes:

- Not more than one output should be tested at a time. Duration of the short circuit should not exceed 1 second. V_{OUT}=0.5V has been chosen to avoid test problems caused by tester ground degradation. Tested initially and after any design or process changes that may affect these parameters.
- Typical I_{CC} is measured with V_{CC} = 3.3V, T_A = 25°C, RFEN = LOW, and outputs unloaded.

DC Characteristics (I/O)

Input/ Output Standard	V _{REF} (V)		V _{CCIO} (V)	V _{OH} (V)		V _{OL} (V)		V _{IH} (V)		V _{IL} (V)	
	Min.	Max.		@ I _{OH} =	V _{OH} (Min.)	@ I _{OL} =	V _{OL} (Max.)	Min.	Max.	Min.	Max.
LVTTTL			3.3	-4 mA	2.4	4 mA	0.4	2.0V	V _{CCIO} +0.3	-0.3V	0.8V
LVC MOS			3.3	-0.1 mA	V _{CCIO} -0.2V	0.1 mA	0.2	2.0V	V _{CCIO} +0.3	-0.3V	0.8V
LVC MOS3			3.0	-0.1 mA	V _{CCIO} -0.2V	0.1 mA	0.2	2.0V	V _{CCIO} +0.3	-0.3V	0.8V
LVC MOS2			2.5	-0.1 mA	2.1	0.1 mA	0.2	1.7V	V _{CCIO} +0.3	-0.3V	0.7V
				-1.0 mA	2.0	1.0 mA	0.4				
				-2.0 mA	1.7	2.0 mA	0.7				
LVC MOS1 8			1.8	-0.1 mA	V _{CCIO} -0.2V	0.1 mA	0.2	0.65V _{CCIO}	V _{CCIO} +0.3	-0.3V	0.35V _{CCIO}
				-2 mA	V _{CCIO} -0.45V	2.0 mA	0.45				
3.3V PCI			3.3	-0.5 mA	0.9V _{CCIO}	1.5 mA	0.1V _{CCIO}	0.5V _{CCIO}	V _{CCIO} +0.5	-0.5V	0.3V _{CCIO}
GTL+	0.9	1.1	Note 7			Note 8	0.6	V _{REF} +0.2			V _{REF} -0.2
SSTL3 I	1.3	1.7	3.3	-8 mA	V _{CCIO} -1.1V	8 mA	0.7	V _{REF} +0.2	V _{CCIO} +0.3	-0.3V	V _{REF} -0.2
SSTL3 II	1.3	1.7	3.3	-16 mA	V _{CCIO} -0.9V	16 mA	0.5	V _{REF} +0.2	V _{CCIO} +0.3	-0.3V	V _{REF} -0.2
SSTL2 I	1.15	1.35	2.5	-7.6 mA	V _{CCIO} - 0.62V	7.6 mA	0.54	V _{REF} +1.8	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1 8
SSTL2 II	1.15	1.35	2.5	-15.2 mA	V _{CCIO} -0.43V	15.2 mA	0.35	V _{REF} +1.8	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1 8
HSTL I	0.68	0.9	1.5	-8 mA	V _{CCIO} -0.4V	8 mA	0.4	V _{REF} +1.0	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1
HSTL II	0.68	0.9	1.5	-16 mA	V _{CCIO} -0.4V	16 mA	0.4	V _{REF} +1.0	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1
HSTL III	0.68	0.9	1.5	-8 mA	V _{CCIO} -0.4V	24 mA	0.4	V _{REF} +1.0	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1
HSTL IV	0.68	0.9	1.5	-8 mA	V _{CCIO} -0.4V	48 mA	0.4	V _{REF} +1.0	V _{CCIO} +0.3	-0.3V	V _{REF} -0.1

Parameter	Description	Test Conditions	Min.	Max.	Unit
SD Pin LVTTTL Inputs					
V _{IHT}	Input HIGH Voltage	Low = 2.0V, High = V _{CC} + 0.5V	2.0	V _{CC} - 0.3	V
V _{ILT}	Input LOW Voltage	Low = -3.0V, High = 0.8V	-0.3	0.8	V
I _{IHT}	Input HIGH Current	V _{CC} = Max., V _{IN} = V _{CC}		50	μA
I _{ILT}	Input LOW Current	V _{CC} = Max., V _{IN} = 0V		-50	μA
REFCLK LVPECL Compatible Inputs					
V _{INSGLE}	Input Single-ended Swing		200	600	mV
V _{DIFFE}	Input Differential Voltage		400	1200	mV
V _{IEHH}	Highest Input HIGH Voltage		V _{CC} - 1.2	V _{CC} - 0.3	V
V _{IELL}	Lowest Input LOW Voltage		V _{CC} - 2.0	V _{CC} - 1.45	V
I _{IEH}	Input HIGH Current	V _{IN} = V _{IEHH} Max.		750	μA
I _{IEL}	Input LOW Current	V _{IN} = V _{IELL} Min.	-200		μA
General Transmitter Differential CML Compatible Outputs (All High-Speed PSI)					
V _{OHC}	Output HIGH Voltage (V _{CC} Referenced)	100Ω differential load	V _{CC} - 0.5	V _{CC} - 0.15	V
V _{OLC}	Output LOW Voltage (V _{CC} Referenced)	100Ω differential load	V _{CC} - 1.2	V _{CC} - 0.7	V
V _{SGLCO}	Output Single-ended Voltage	100Ω differential load	280	800	mV

Notes:

7. See "Power-up Sequence Requirements" for V_{CCIO} requirement.
8. 25Ω resistor terminated to termination voltage of 1.5V.



Programmable Serial Interface (High Speed Devices)

PRELIMINARY

Parameter	Description	Test Conditions	Min.	Max.	Unit
Transmitter Differential CML Compatible Outputs (P25G01K100, P25G02K100 only)					
V _{DIFF}	Differential Output	100Ω differential load	1000	1600	mV
I _{ACCM}	AC Common Mode Current			5	μA
V _{ACCM}	AC Common Mode Voltage			25	mV
Z _D	Differential Output Impedance		75	125	Ω
Z _{SE}	Single Ended Output Impedance		30	75	Ω
Z _{MSE}	Single Ended Output Impedance Matching Within a Single Lane			10	%
I _{DSHORT}	Short Circuit Current		-100	100	mA
Transmitter Differential CML Compatible Outputs (S25G01K100, S25G02K100 only)					
V _{DIFFOC}	Output Differential Swing	100Ω differential load	560	1500	mV
General Receiver Differential CML Compatible Inputs (All High-Speed PSI)					
V _{INSGLC}	Input Single-ended Swing		25	600	mV
V _{ICHH}	Highest Input HIGH Voltage			V _{CC}	V
V _{ICLL}	Lowest Input LOW Voltage		1.2		V
I _{ICH}	Input HIGH Current	V _{IN} = V _{ICHH} Max.		47	μA
I _{ICL}	Input LOW Current	V _{IN} = V _{ICLL} Min.		20	μA
Receiver Differential CML Compatible Inputs (P25G01K100, P25G02K100 only)					
V _{RSENSE}	Input Sensitivity		175		mV
Z _{VTT}	V _{TT} Impedance			30	Ω
L _{DR}	Differential Return Loss		10		dB
L _{CMR}	Common Mode Return Loss		6		dB
V _{RSO}	Voltage Threshold		20		mV
V _{RMAX}	Maximum Input Voltage (p-p)			1.6	V
Receiver Differential CML Compatible Inputs (S25G01K100, S25G02K100 only)					
V _{DIFFC}	Input Differential Voltage		50	1200	mV

Configuration Parameters

Parameter	Description	Min.	Unit
t _{RECONFIG}	Reconfig pin LOW time before it goes HIGH	200	ns

Power-up Sequence Requirements

- Upon power-up, all the outputs remain three-stated until all the V_{CC} pins have powered-up to the nominal voltage and the part has completed configuration.
- The part will not start configuration until V_{CC}, V_{CCIO}, V_{CCJTAG}, V_{CCNFG}, V_{CCPLL} and V_{CEPVCEP} have reached nominal voltage.
- V_{CC} pins can be powered up in any order. This includes V_{CC}, V_{CCIO}, V_{CCJTAG}, V_{CCNFG}, V_{CCPLL} and V_{CEP}.
- All V_{CCIO}s on a bank should be tied to the same potential and powered up together.
- All V_{CCIO}s (even the unused banks) need to be powered up to at least 1.5V before configuration has completed.
- Maximum ramp time for all V_{CC}s should be 0V to nominal voltage in 100 ms.



Switching Characteristics

Timing Parameter Values

Parameter	Description	Min.	Max.	Unit
Combinatorial Mode Parameters				
t_{PD}	Delay from any pin input, through any cluster on the channel associated with that pin input, to any pin output on the horizontal or vertical channel associated with that cluster		7.5	ns
t_{EA}	Global control to output enable		5.0	ns
t_{ER}	Global control to output disable		5.0	ns
t_{PRR}	Asynchronous macrocell RESET or PRESET recovery time from any pin input on the horizontal or vertical channel associated with the cluster the macrocell is in	6.0		ns
t_{PRO}	Asynchronous macrocell RESET or PRESET from any pin input on the horizontal or vertical channel associated with the cluster that the macrocell is in to any pin output on those same channels	10		ns
t_{PRW}	Asynchronous macrocell RESET or PRESET minimum pulse width, from any pin input to a macrocell in the farthest cluster on the horizontal or vertical channel the pin is associated with	3.6		ns
Synchronous Clocking Parameters				
t_{MCS}	Set-up time of any input pin to a macrocell in any cluster on the channel associated with that input pin, relative to a global clock	3.0		ns
t_{MCH}	Hold time of any input pin to a macrocell in any cluster on the channel associated with that input pin, relative to a global clock	0.0		ns
t_{MCCO}	Global clock to output of any macrocell to any output pin on the horizontal or vertical channel associated with the cluster that macrocell is in		6.0	ns
t_{IOS}	Set-up time of any input pin to the I/O cell register associated with that pin, relative to a global clock	1.0		ns
t_{IOH}	Hold time of any input pin to the I/O cell register associated with that pin, relative to a global clock	1.0		ns
t_{IOCO}	Clock to output of an I/O cell register to the output pin associated with that register		4.0	ns
t_{SCS}	Macrocell clock to macrocell clock through array logic within the same cluster	4.0		ns
t_{SCS2}	Macrocell clock to macrocell clock through array logic in different clusters on the same channel	5.0		ns
t_{ICS}	I/O register clock to any macrocell clock in a cluster on the channel the I/O register is associated with	5.0		ns
t_{OCS}	Macrocell clock to any I/O register clock on the horizontal or vertical channel associated with the cluster that the macrocell is in	5.0		ns
t_{CHZ}	Clock to output disable (high-impedance)		3.5	ns
t_{CLZ}	Clock to output enable (low-impedance)	2.0		ns
f_{MAX}	Maximum frequency with internal feedback—within the same cluster		250	MHz
f_{MAX2}	Maximum frequency with internal feedback—within different clusters at the opposite ends of a horizontal or vertical channel		200	MHz
Product Term Clocking Parameters				
t_{MCSPT}	Set-up time for macrocell used as input register, from input to product term clock	3.0		ns
t_{MCHPT}	Hold time of macrocell used as an input register	1.0		ns
t_{MCCOPT}	Product term clock to output delay from input pin		8.0	ns
t_{SCS2PT}	Register to register delay through array logic in different clusters on the same channel using a product term clock	6.5		ns

Note:

9. Add t_{CHSW} to signals making a horizontal to vertical channel switch or vice-versa.

Switching Characteristics

Timing Parameter Values (continued)

Parameter	Description	Min.	Max.	Unit
Channel Interconnect Parameters				
t_{CHSW}	Adder for a signal to switch from a horizontal to vertical channel and vice-versa		1.0	ns
t_{CL2CL}	Cluster to Cluster delay adder (through channels and channel PIM)		2.0	ns
Miscellaneous Parameters				
t_{CPLD}	Delay from the input of a cluster PIM, through a macrocell in the cluster, back to a cluster PIM input. This parameter can be added to the t_{PD} and t_{SCS} parameters for each extra pass through the AND/OR array required by a given signal path		3.0	ns
t_{MCCD}	Adder for carry chain logic per macrocell		0.25	ns
PLL Parameters				
t_{MCCJ}	Maximum cycle to cycle jitter time		0.50	ns
t_{DWSA}	PLL delay with skew adjustment		0.35	ns
t_{DWOSA}	PLL delay without any skew adjustment		0.35	ns
t_{LOCK}	Lock time for the PLL		3.0	ms
$f_{PLLO}^{[10]}$	Output frequency of the PLL	6.2	266	MHz
$f_{PLLI}^{[10]}$	Input frequency of the PLL	25	133	MHz

Cluster Memory Timing Parameter Values

Parameter	Description	200		Unit
		Min.	Max.	
Asynchronous Mode Parameters				
t_{CLMAA}	Cluster memory access time. Delay from address change to read data out		11	ns
t_{CLMPWE}	Write enable pulse width	6.0		ns
t_{CLMSA}	Address set-up to the beginning of write enable	2.0		ns
t_{CLMHA}	Address hold after the end of write enable with both signals from the same I/O block	1.0		ns
t_{CLMSD}	Data set-up to the end of write enable	6.0		ns
t_{CLMHD}	Data hold after the end of write enable	0.5		ns
Synchronous Mode Parameters				
$t_{CLMICYC1}$	Clock cycle time for flow-through read and write operations (from macrocell register through cluster memory back to a macrocell register in the same cluster)	10		ns
$t_{CLMICYC2}$	Clock cycle time for pipelined read and write operations (from cluster memory input register through the memory to cluster memory output register)	5.0		ns
t_{CLMS}	Address, data, and WE set-up time of pin inputs, relative to a global clock	3.0		ns
t_{CLMH}	Address, data, and WE hold time of pin inputs, relative to a global clock	0.0		ns
t_{CLMDV1}	Global clock to data valid on output pins for flow through data		11	ns
t_{CLMDV2}	Global clock to data valid on output pins for pipelined data		7.5	ns

Note:

10. Refer to page 15 and the application note titled "PSI PLL and Clock Tree" for details on the PLL operation & specification.



Cluster Memory Timing Parameter Values (continued)

$t_{CLMMACS1}$	Cluster memory input clock to macrocell clock in the same cluster	8.0		ns
$t_{CLMMACS2}$	Cluster memory output clock to macrocell clock in the same cluster	5.0		ns
$t_{MACCLMS1}$	Macrocell clock to cluster memory input clock in the same cluster	4.0		ns
$t_{MACCLMS2}$	Macrocell clock to cluster memory output clock in the same cluster	6.5		ns
Internal Parameters				
$t_{CLMCLAA}$	Asynchronous cluster memory access time from input of cluster to output of cluster	6.0		ns

Channel Memory Timing Parameter Values

Parameter	Description	Min.	Max.	Unit
Dual-Port Asynchronous Mode Parameters				
t_{CHMAA}	Channel memory access time. Delay from address change to read data out		11	ns
t_{CHMPWE}	Write enable pulse width	6.0		ns
t_{CHMSA}	Address set-up to the beginning of write enable	2.0		ns
t_{CHMHA}	Address hold after the end of write enable with both signals from the same I/O block	1.0		ns
t_{CHMSD}	Data set-up to the end of write enable	6.0		ns
t_{CHMHD}	Data hold after the end of write enable	0.5		ns
t_{CHMBA}	Channel memory asynchronous dual port address match (busy access time)		9.0	ns
Dual-Port Synchronous Mode Parameters				
$t_{CHMCYC1}$	Clock cycle time for flow through read and write operations (from macrocell register through channel memory back to a macrocell register in the same cluster)	10		ns
$t_{CHMCYC2}$	Clock cycle time for pipelined read and write operations (from channel memory input register through the memory to channel memory output register)	5.0		ns
t_{CHMS}	Address, data, and WE set-up time of pin inputs, relative to a global clock	3.3		ns
t_{CHMH}	Address, data, and WE hold time of pin inputs, relative to a global clock	0.0		ns
t_{CHMDV1}	Global clock to data valid on output pins for flow through data		11	ns
t_{CHMDV2}	Global clock to data valid on output pins for pipelined data		7.5	ns
t_{CHMBDV}	Channel memory synchronous dual-port address match (busy, clock to data valid)		9.0	ns
$t_{CHMMACS1}$	Channel memory input clock to macrocell clock in the same cluster	9.0		ns
$t_{CHMMACS2}$	Channel memory output clock to macrocell clock in the same cluster	5.0		ns
$t_{MACCHMS1}$	Macrocell clock to channel memory input clock in the same cluster	5.0		ns
$t_{MACCHMS2}$	Macrocell clock to channel memory output clock in the same cluster	7.0		ns
Synchronous FIFO Data Parameters				
t_{CHMCLK}	Read and write minimum clock cycle time	5.0		ns
t_{CHMFS}	Data, read enable, and write enable set-up time relative to pin inputs	4.0		ns
t_{CHMFH}	Data, read enable, and write enable hold time relative to pin inputs	0.0		ns
$t_{CHMFRDV}$	Data access time to output pins from rising edge of read clock (read clock to data valid)	7.0		
$t_{CHMMACS}$	Channel memory FIFO read clock to macrocell clock for read data	5.0		ns
$t_{MACCHMS}$	Macrocell clock to channel memory FIFO write clock for write data	5.0		ns



Channel Memory Timing Parameter Values (continued)

Synchronous FIFO Flag Parameters				
t_{CHMFO}	Read or write clock to respective flag output at output pins	11		ns
$t_{CHMMACF}$	Read or write clock to macrocell clock with FIFO flag	9		ns
t_{CHMFRS}	Master Reset Pulse Width	5.0		ns
$t_{CHMFRSR}$	Master Reset Recovery Time		4.0	ns
$t_{CHMFRSF}$	Master Reset to Flag and Data Output Time		10.0	ns
$t_{CHMSKEW1}$	Read/Write Clock Skew Time for Full Flag		2.0	ns
$t_{CHMSKEW2}$	Read/Write Clock Skew Time for Empty Flag		2.0	ns
$t_{CHMSKEW3}$	Read/Write Clock Skew Time for Boundary Flags		5.0	ns
Internal Parameters				
$t_{CHMCHAA}$	Asynchronous channel memory access time from input of channel memory to output of channel memory	7.0		ns

High-Speed PSI Transceiver Timing Parameter Values

Parameter	Description	Min.	Max.	Unit
Transceiver Interfacing Timing Parameters				
t_{TS}	TXCLK Frequency (must be frequency coherent to REFCLK)	154.5	156.5	MHz
t_{TXCLK}	TXCLK Period	6.38	6.47	ns
t_{TXCLKD}	TXCLK Duty Cycle	40	60	%
t_{TXCLKR}	TXCLK Rise Time	0.3	1.5	ns
t_{TXCLKF}	TXCLK Fall Time	0.3	1.5	ns
t_{TXDS}	Write Data Set-up to \uparrow of TXCLK	1.5		ns
t_{TXDH}	Write Data Hold from \uparrow of TXCLK	.5		ns
t_{RS}	RXCLK Frequency	154.5	156.5	MHz
t_{RXCLK}	RXCLK Period	6.38	6.47	ns
t_{RXCLKD}	RXCLK Duty Cycle	43	57	%
t_{RXCLKR}	RXCLK Rise Time ^[11]	0.1	1.5	ns
t_{RXCLKF}	RXCLK Fall Time ^[11]	0.1	1.5	ns
t_{RXDS}	Recovered Data Set-up with regard to \uparrow of RXCLK	2.2		ns
t_{RXDH}	Recovered Data Hold with regard to \uparrow of RXCLK	2.2		ns
t_{RXPDP}	Valid Propagation delay	-1.0	1.0	ns

Note:

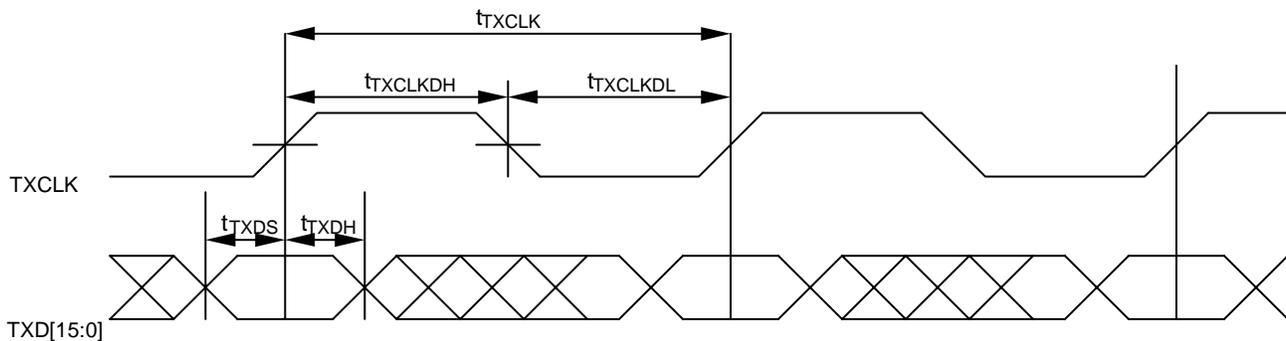
11. For "slow slew rate" output delay adjustments, refer to *Warp* software's static timing analyzer results.



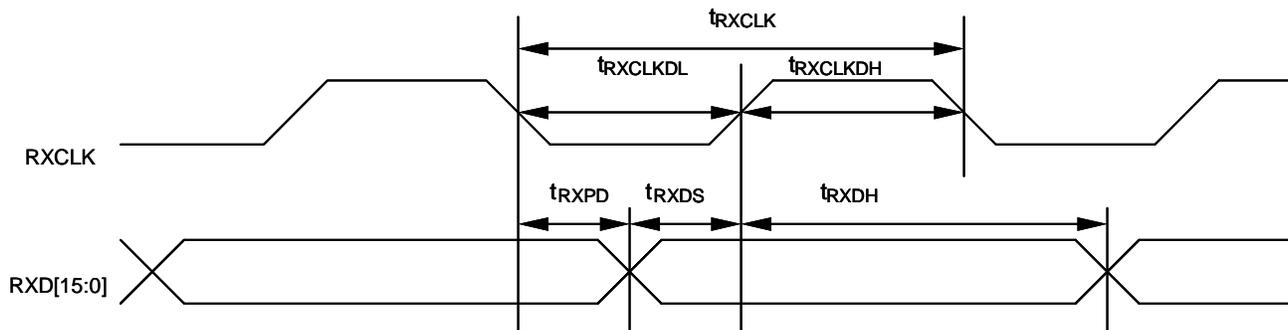
High-Speed PSI Transceiver Timing Parameter Values

Parameter	Description	Min.	Max.	Unit
REFCLK Timing Parameters				
t_{REF}	REFCLK Input Frequency	154.5	156.5	MHz
t_{REFP}	REFCLK Period	6.38	6.47	ns
t_{REFD}	REFCLK Duty Cycle	35	65	%
t_{REFT}	REFCLK Frequency Tolerance (relative to received serial data)	-100	+100	ppm
t_{REFR}	REFCLK Rise Time	0.3	1.5	ns
t_{REFF}	REFCLK Fall Time	0.3	1.5	ns
CML Serial Outputs (P25G01K100,P25G02K100 only)				
t_{DRF}	Driver Rise/Fall Time (20–80% rise, 80–20% fall, 100Ω balanced load)	100		ps
t_{JD}	Deterministic Jitter		0.17	UI
t_{JT}	Total Jitter		0.35	UI
t_{UID}	Unit Interval	400	400	ps
CML Serial Outputs (S25G01K100, S25G02K100 only)				
t_{RISE}	CML Output Rise Time (20–80%, 100Ω balanced load)	60	170	ps
t_{FALL}	CML Output Fall Time (80–20%, 100Ω balanced load)	60	170	ps
t_{TJ}	Total Output Jitter (p-p)		0.05	UI
	Total Output Jitter (rms)		0.007	UI
CML Serial Inputs (P25G01K100, P25G02K100 only)				
t_{EYE}	Eye opening	140		ps
t_{JDR}	Deterministic Jitter at Receiver		0.41	UI
t_{JTR}	Total Jitter at Receiver		0.65	UI

Transmit Interface Timing for High-Speed PSI



Receive Interface timing for High-Speed PSI



Input & Output Standard Timing Delay Adjustments

All the timing specifications in this data sheet are specified based on 3.3V PCI compliant inputs and outputs (fast slew rates^[12]). Apply following adjustments if the inputs and outputs are configured to operate at other standards.

Input/Output Standard	Output Delay Adjustments			Input Delay Adjustments		
	t_{IOD}	t_{EA}	t_{ER}	t_{IOIN}	t_{CKIN}	$t_{IOREGPIN}$
LVTTTL	0.2	0	0	0	0	0
LVC MOS	0.2	0	0	0	0	0
LVC MOS3	0.3	0.05	0	0.1	0.1	0.2
LVC MOS2	0.5	0.1	0	0.2	0.2	0.4
LVC MOS18	2.1	0.7	0.1	0.5	0.4	0.3
3.3V PCI	0	0	0	0	0	0
GTL+	0.6 ^[13]	0.6 ^[13]	0.9 ^[13]	0.5	0.4	0.2
SSTL3 I	-0.3	0.3	0.1	0.5	0.3	0.3
SSTL3 II	-0.4	0.2	0	0.5	0.3	0.3
SSTL2 I	-0.1	0.4	0	0.9	0.5	0.6
SSTL2 II	-0.2	0.2	0	0.9	0.5	0.6
HSTL I	0.6	0.9	0.5	0.5	0.5	0.3
HSTL II	0.4	0.8	0.5	0.5	0.5	0.3
HSTL III	0.6	0.5	0.1	0.5	0.5	0.3
HSTL IV	0.7	0.6	0	0.5	0.5	0.3

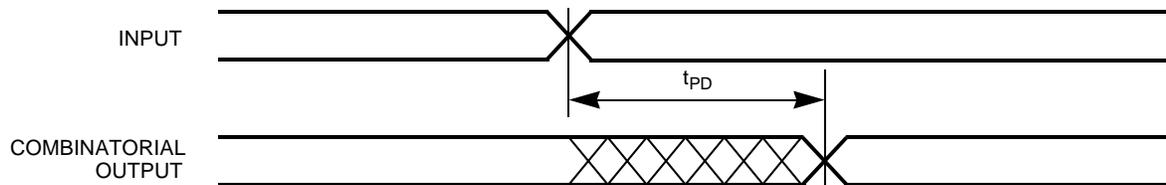
Notes:

12. These delays are based on falling edge output. The rising edge delay depends on the size of pull up resistor and termination voltage.
13. RXCLK rise time and fall time are measured at the 20-80 percentile region of the rising and falling edge of the clock signal

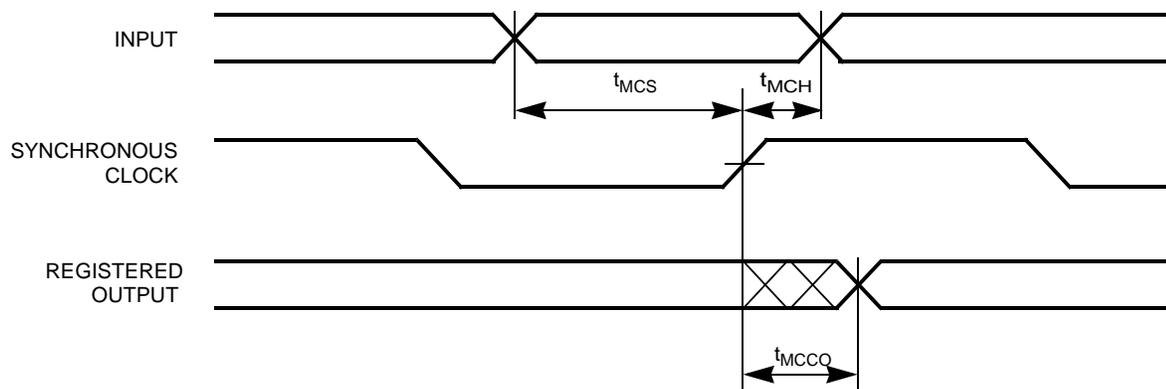
Switching Waveforms

General Switching Waveforms

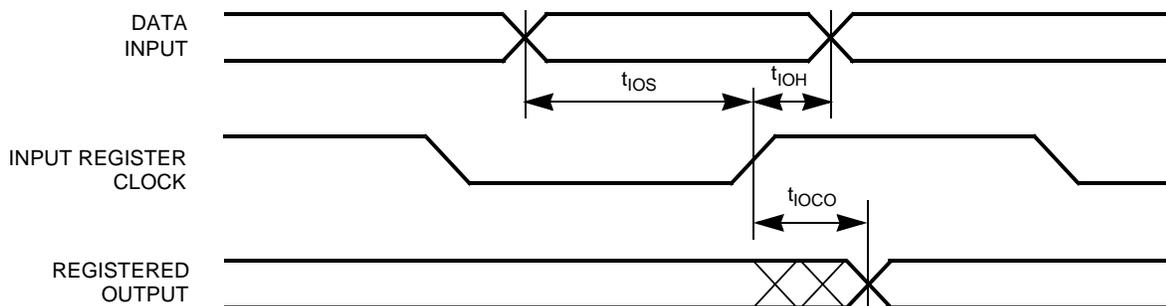
Combinatorial Output



Registered Output with Synchronous Clocking (Macrocell)

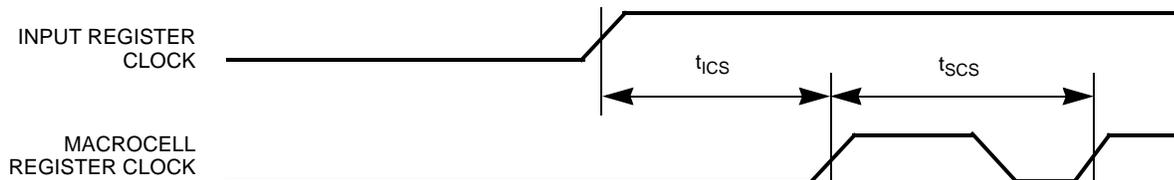


Registered Input in I/O Cell

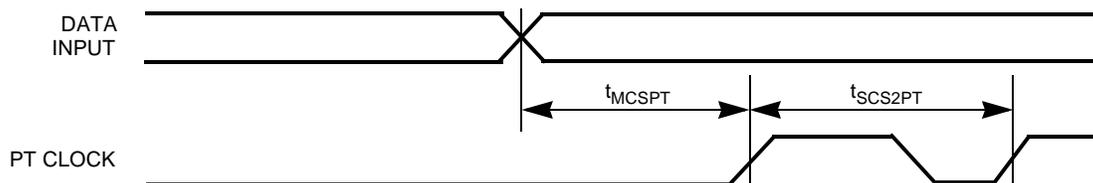


Switching Waveforms (continued)

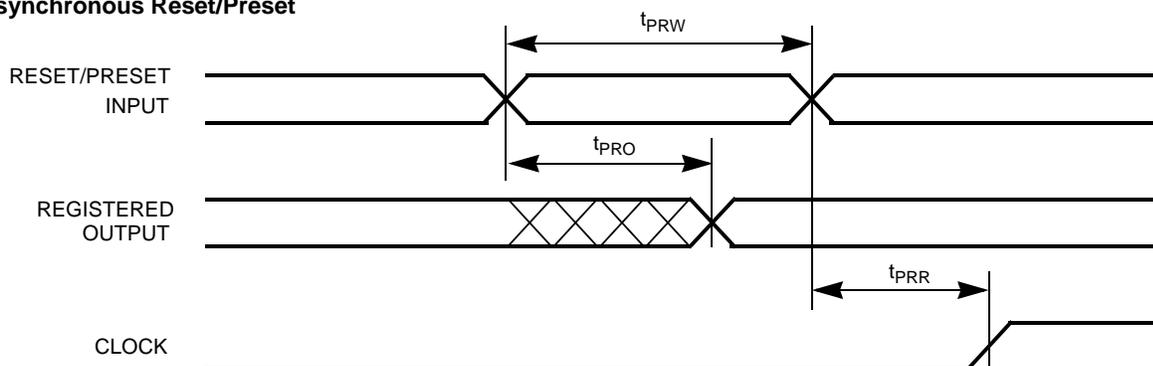
Clock to Clock



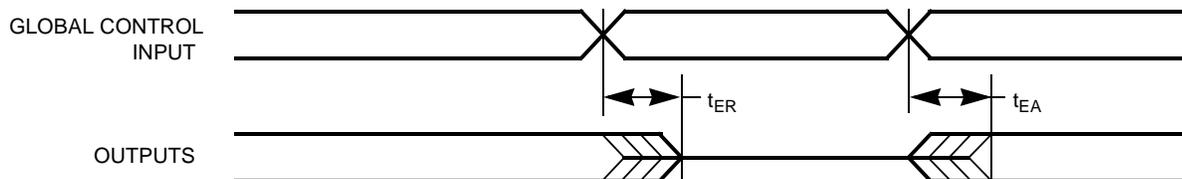
PT Clock to PT Clock



Asynchronous Reset/Preset

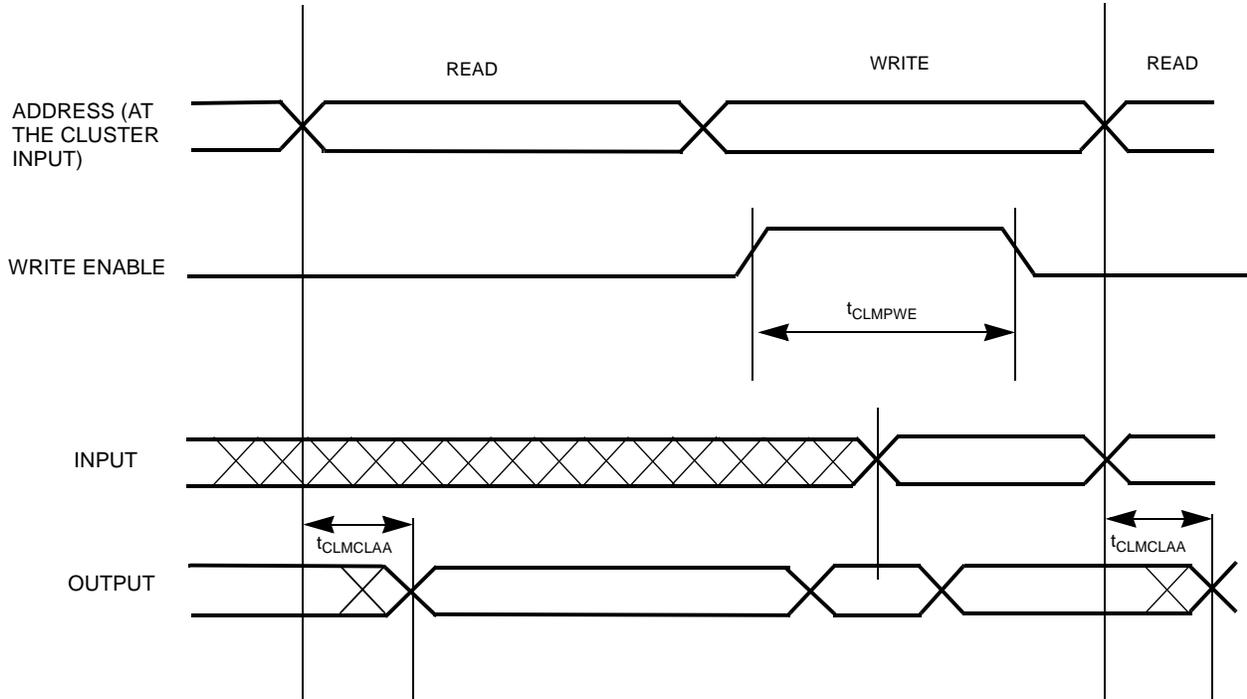


Output Enable/Disable

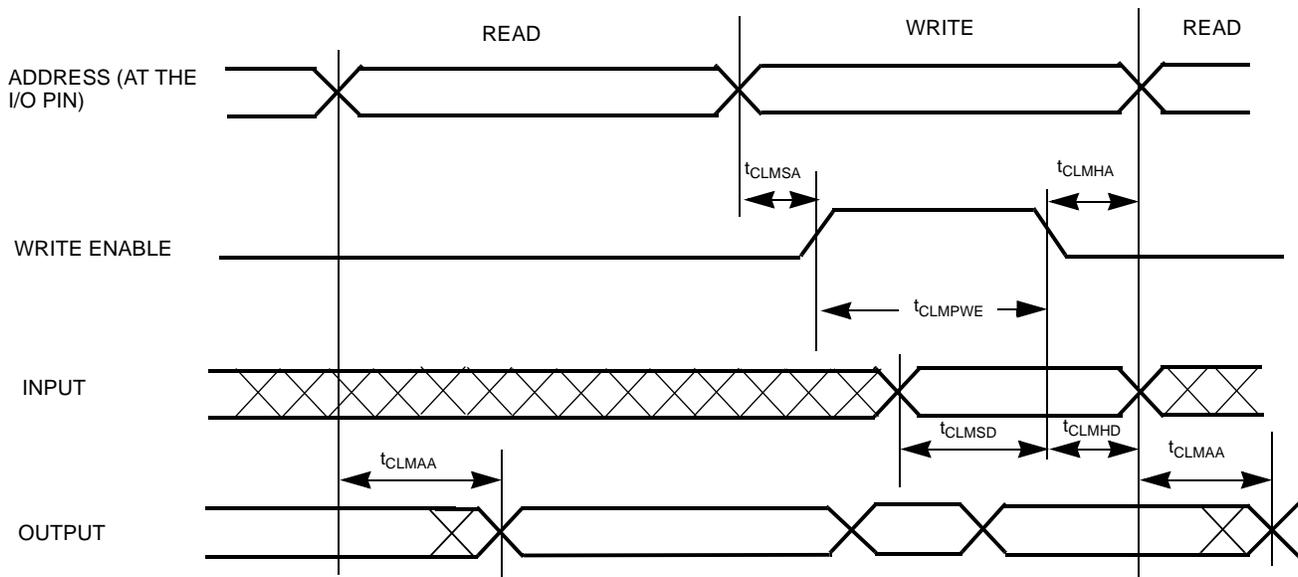


Switching Waveforms (continued)

Cluster Memory Asynchronous Timing

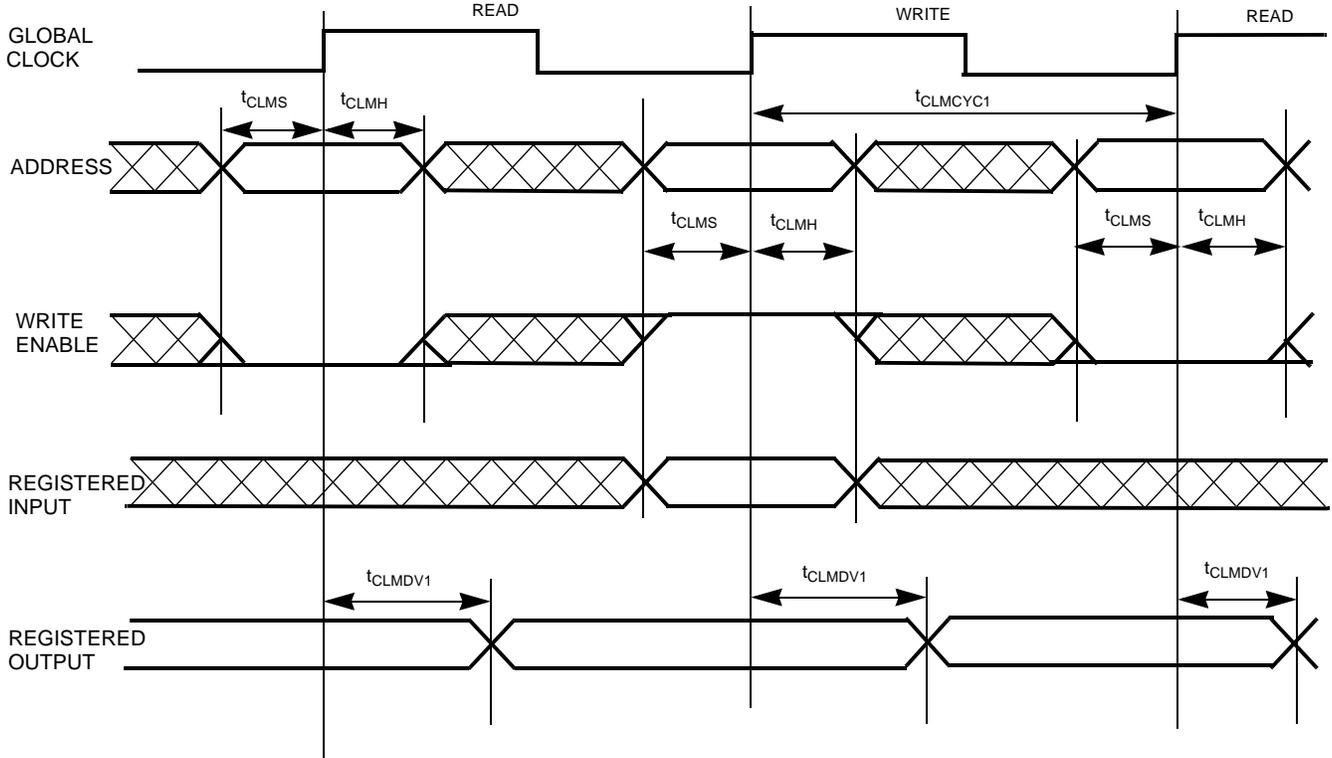


Cluster Memory Asynchronous Timing 2

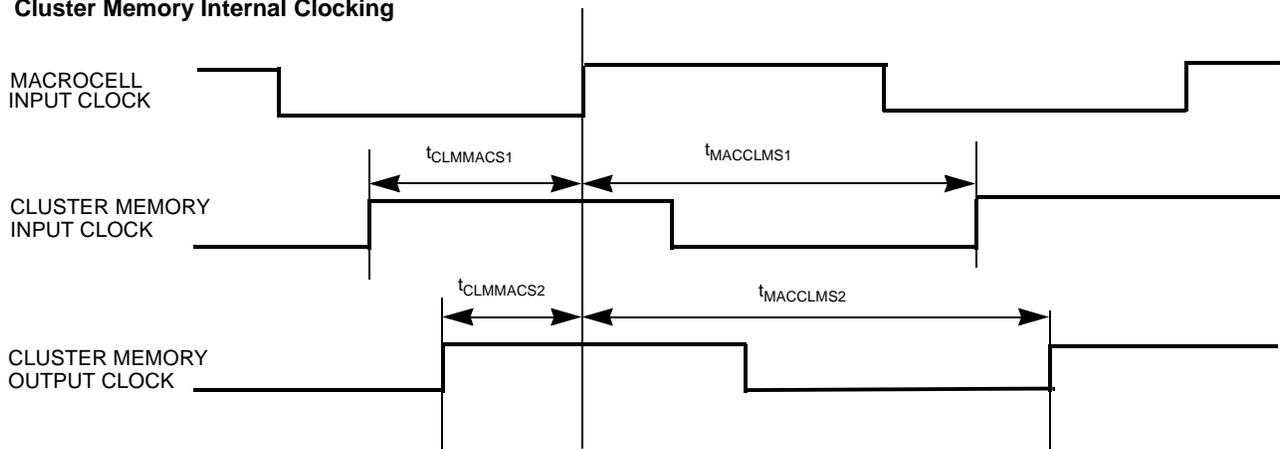


Switching Waveforms (continued)

Cluster Memory Synchronous Timing

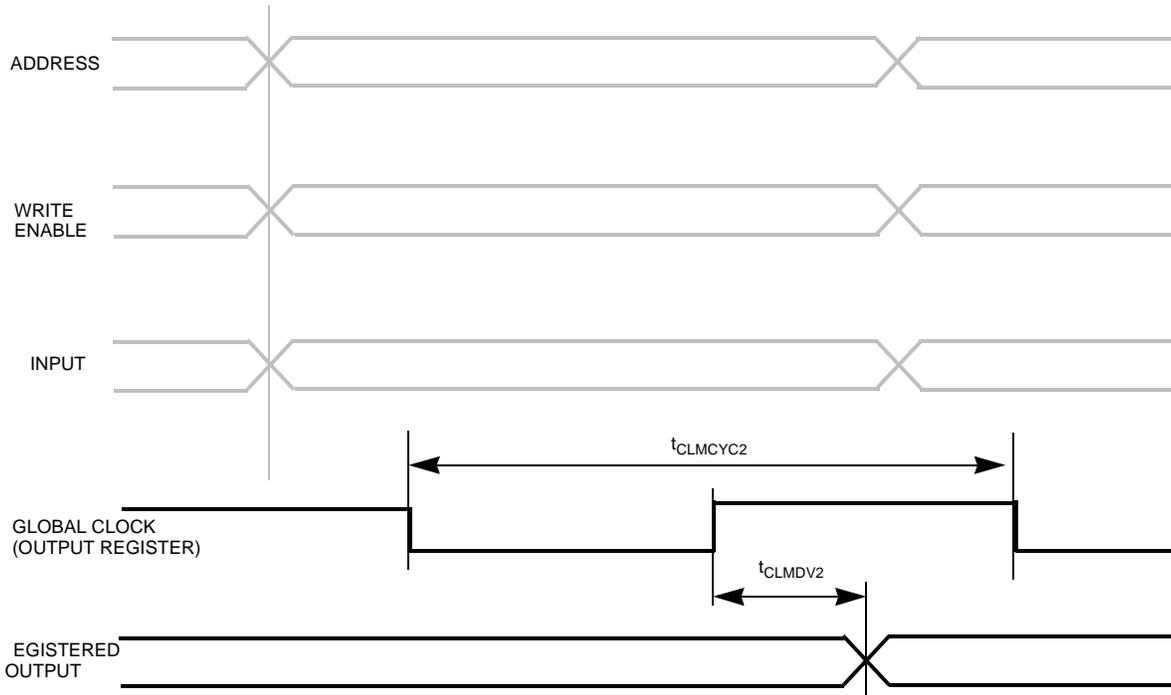


Cluster Memory Internal Clocking

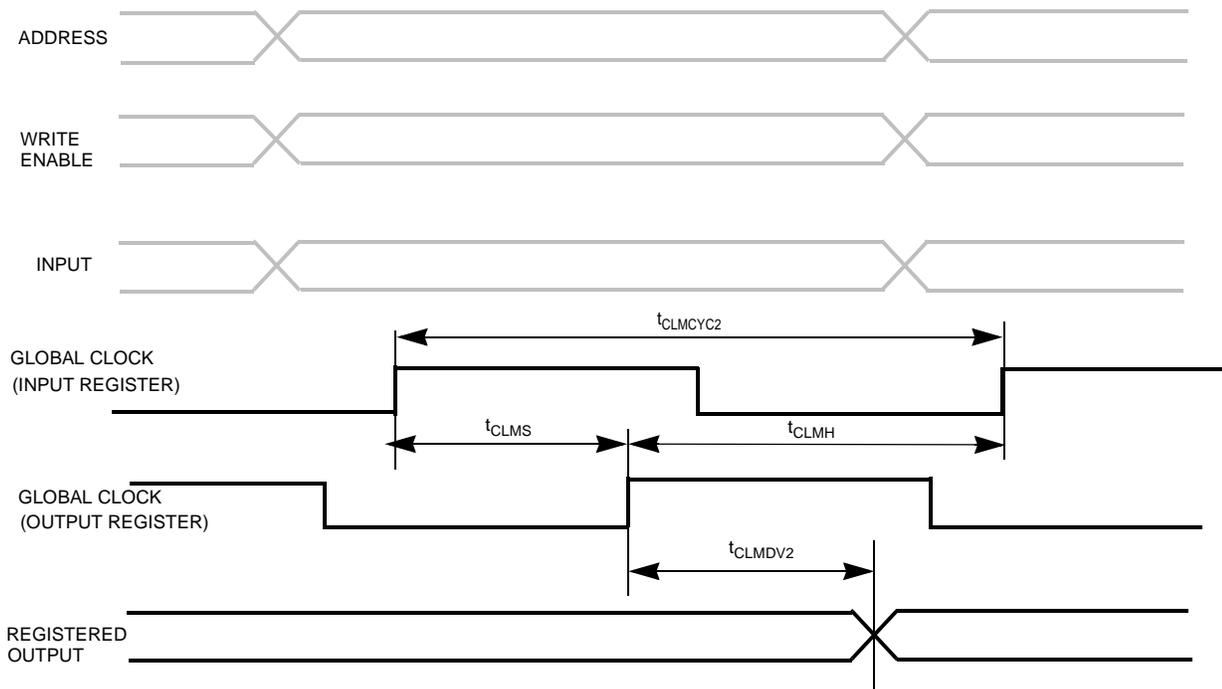


Switching Waveforms (continued)

Cluster Memory Output Register Timing (Asynchronous Inputs)

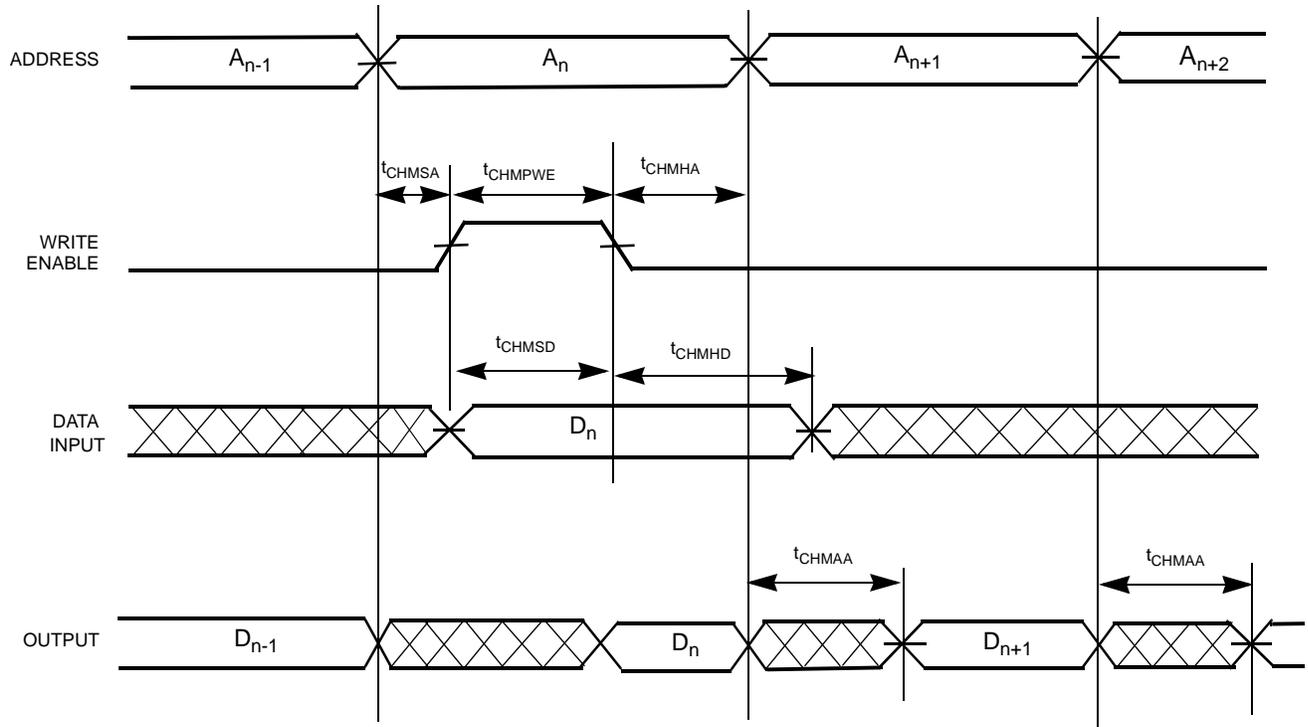


Cluster Memory Output Register Timing (Synchronous Inputs)

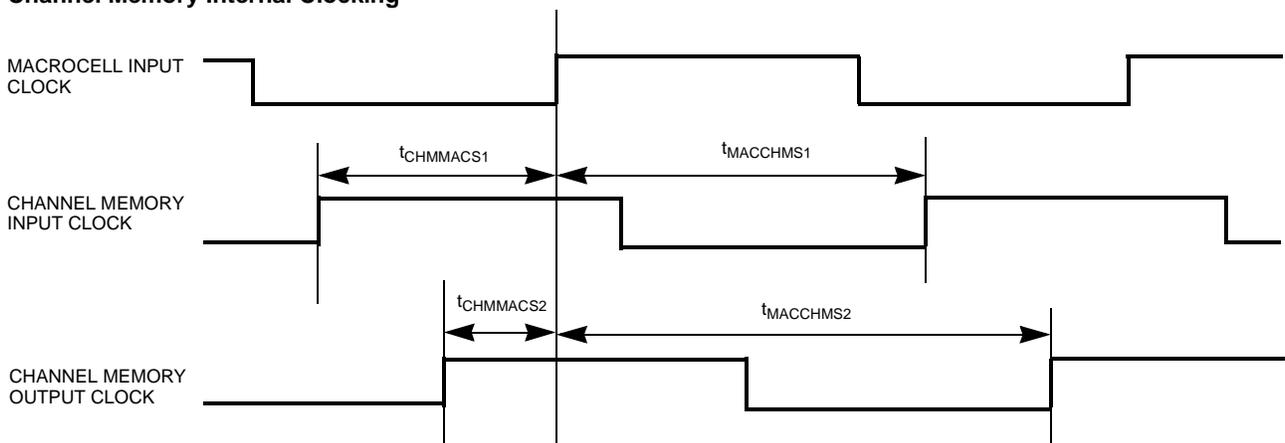


Switching Waveforms (continued)

Channel Memory DP Asynchronous Timing

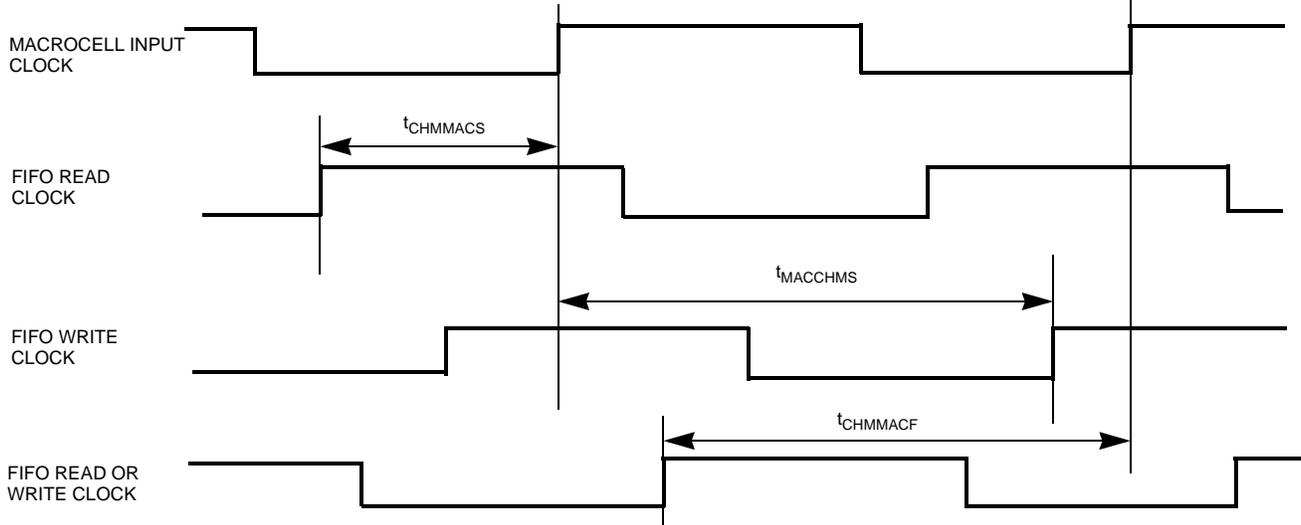


Channel Memory Internal Clocking

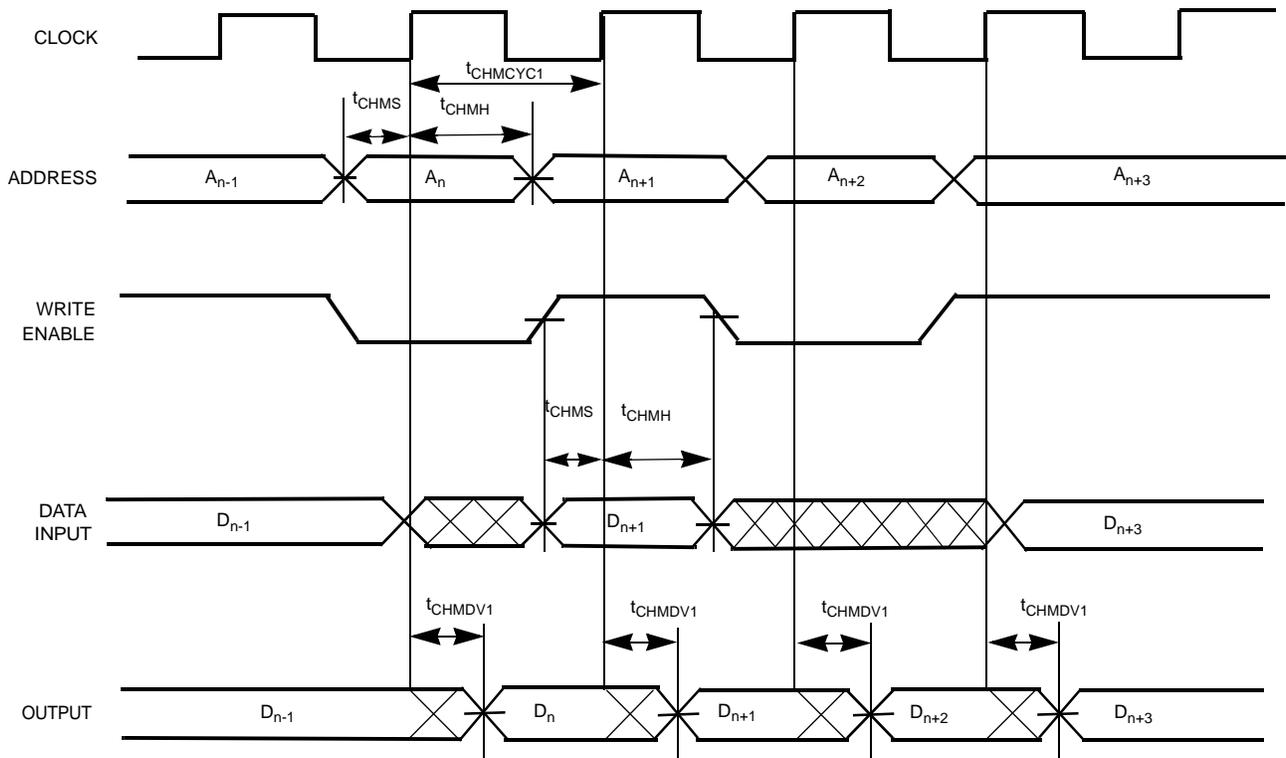


Switching Waveforms (continued)

Channel Memory Internal Clocking 2

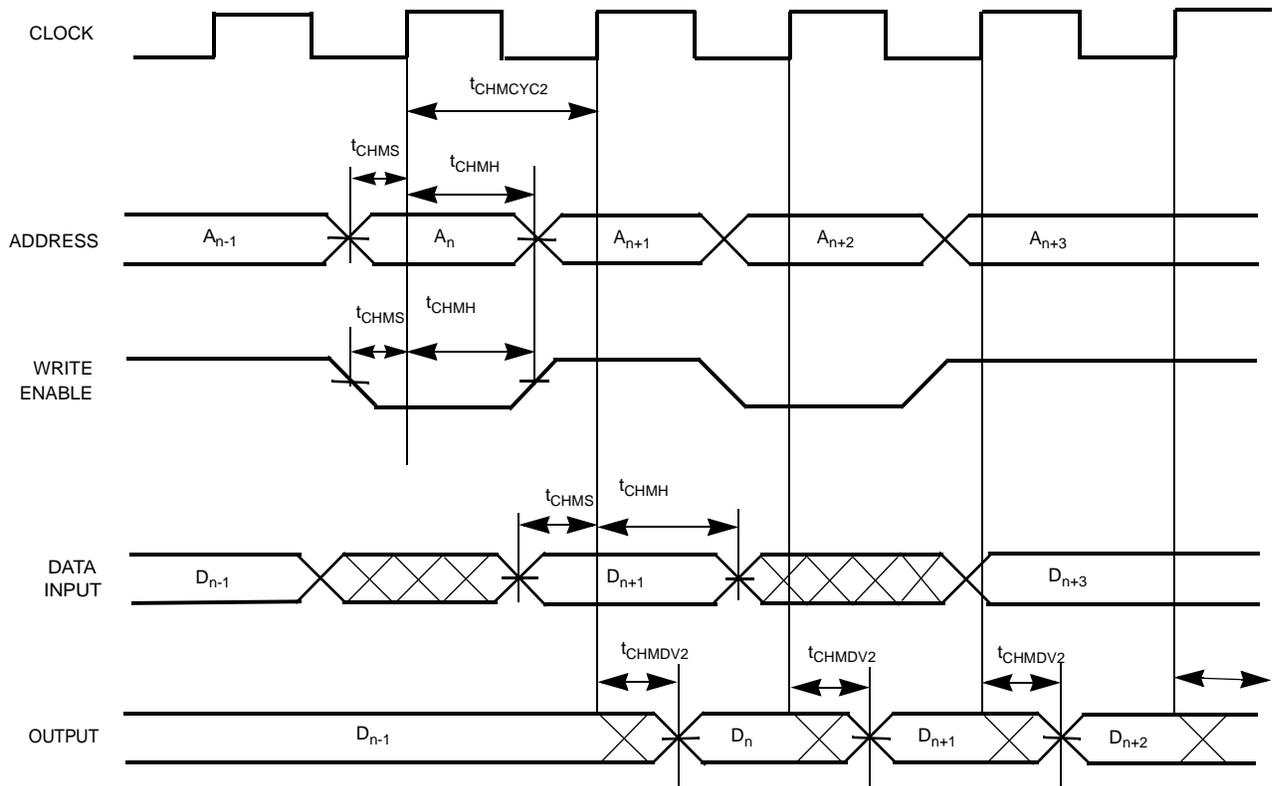


Channel Memory DP SRAM Flow Through R/W Timing

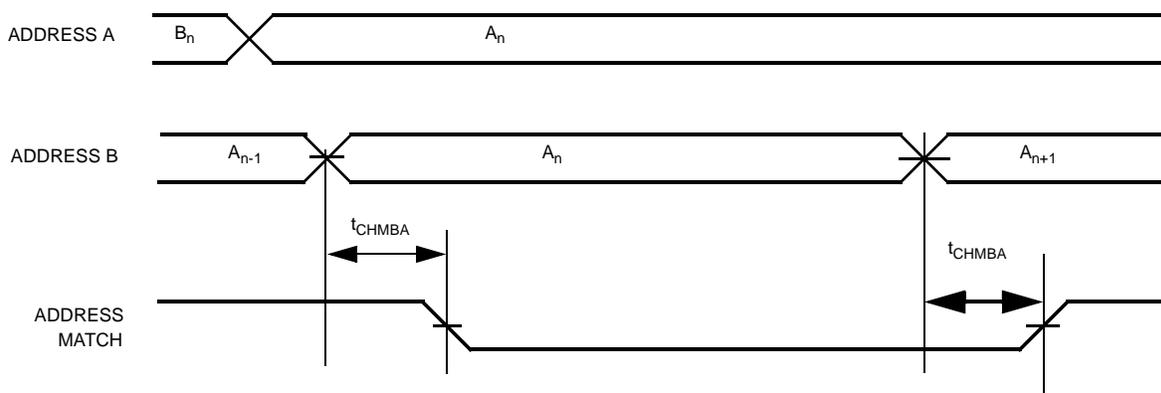


Switching Waveforms (continued)

Channel Memory DP SRAM Pipeline R/W Timing

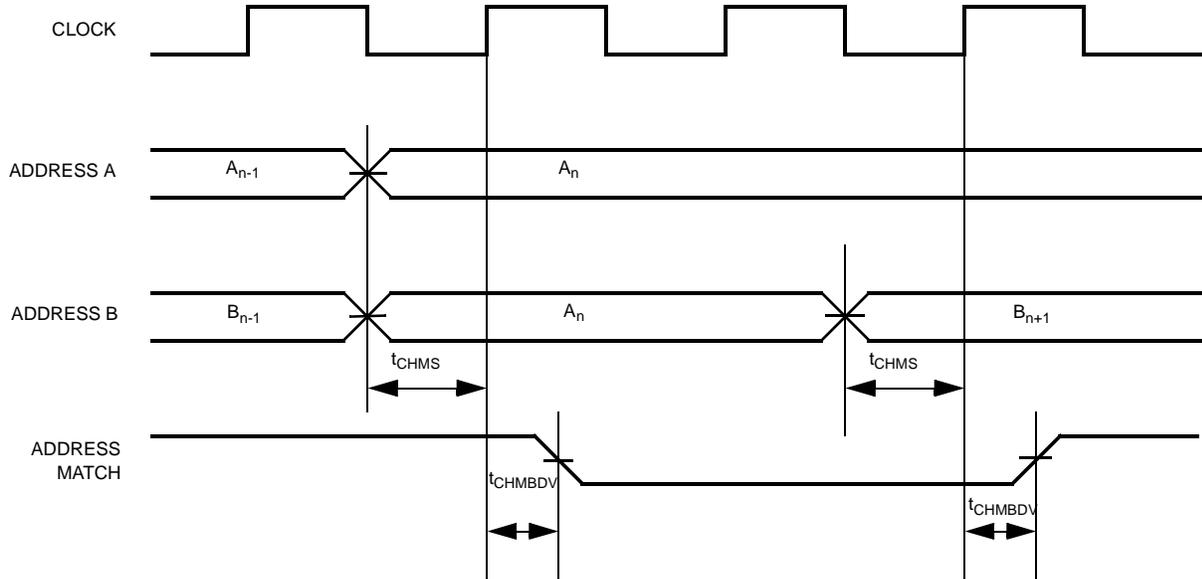


Dual-Port Asynchronous Address Match Busy Signal



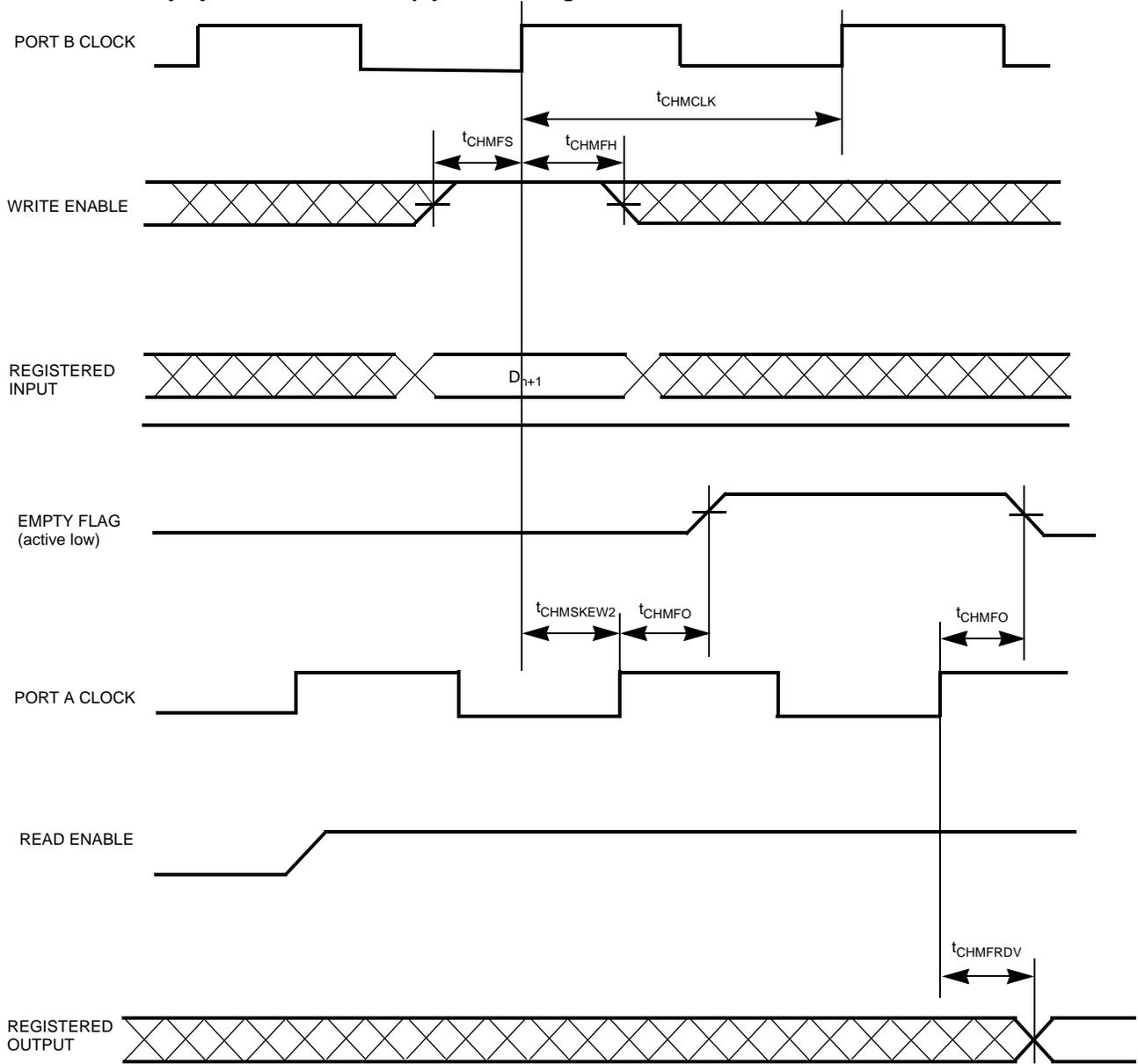
Switching Waveforms (continued)

Dual-Port Synchronous Address Match Busy Signal



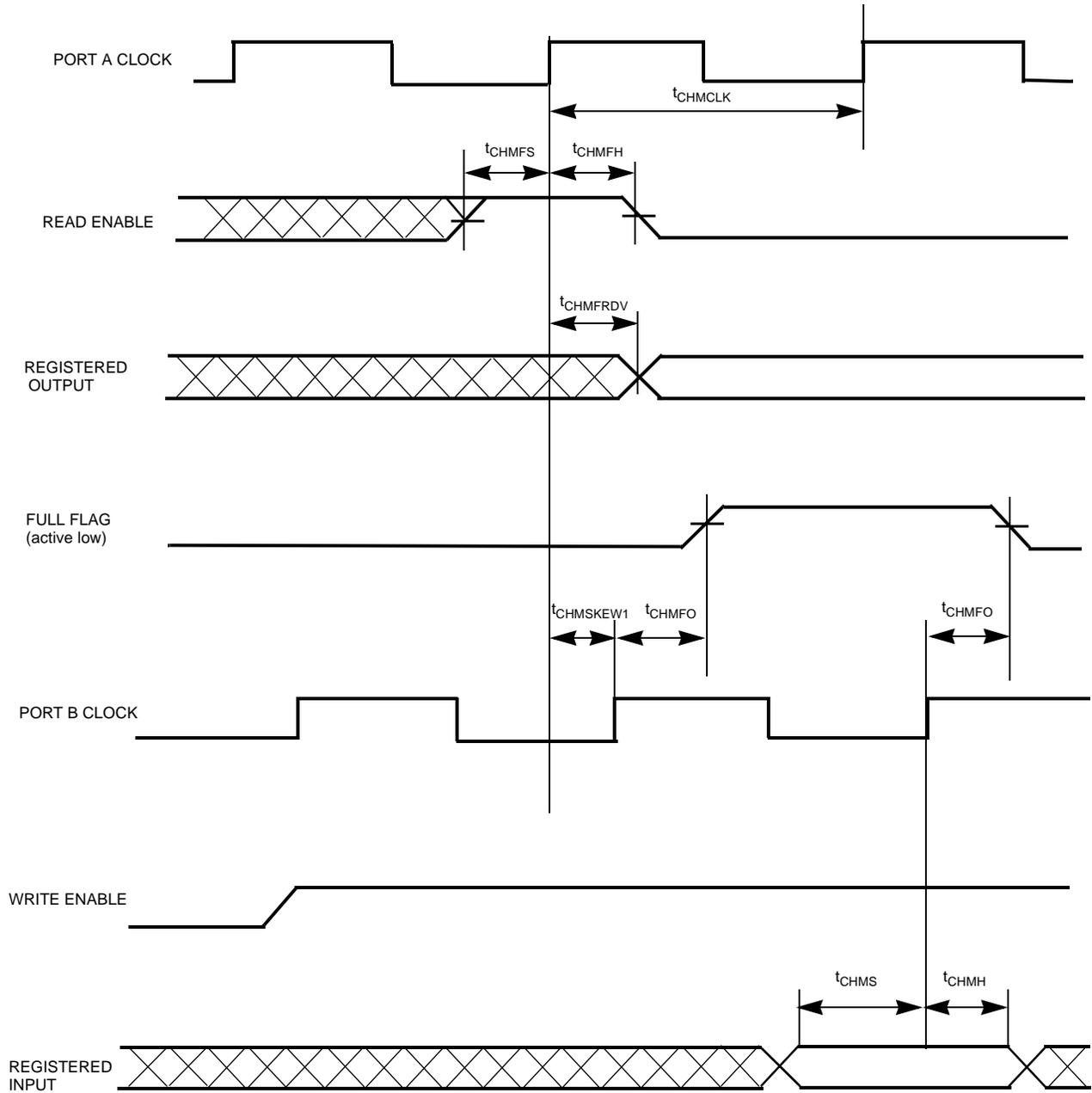
Switching Waveforms (continued)

Channel Memory Synchronous FIFO Empty/Write Timing



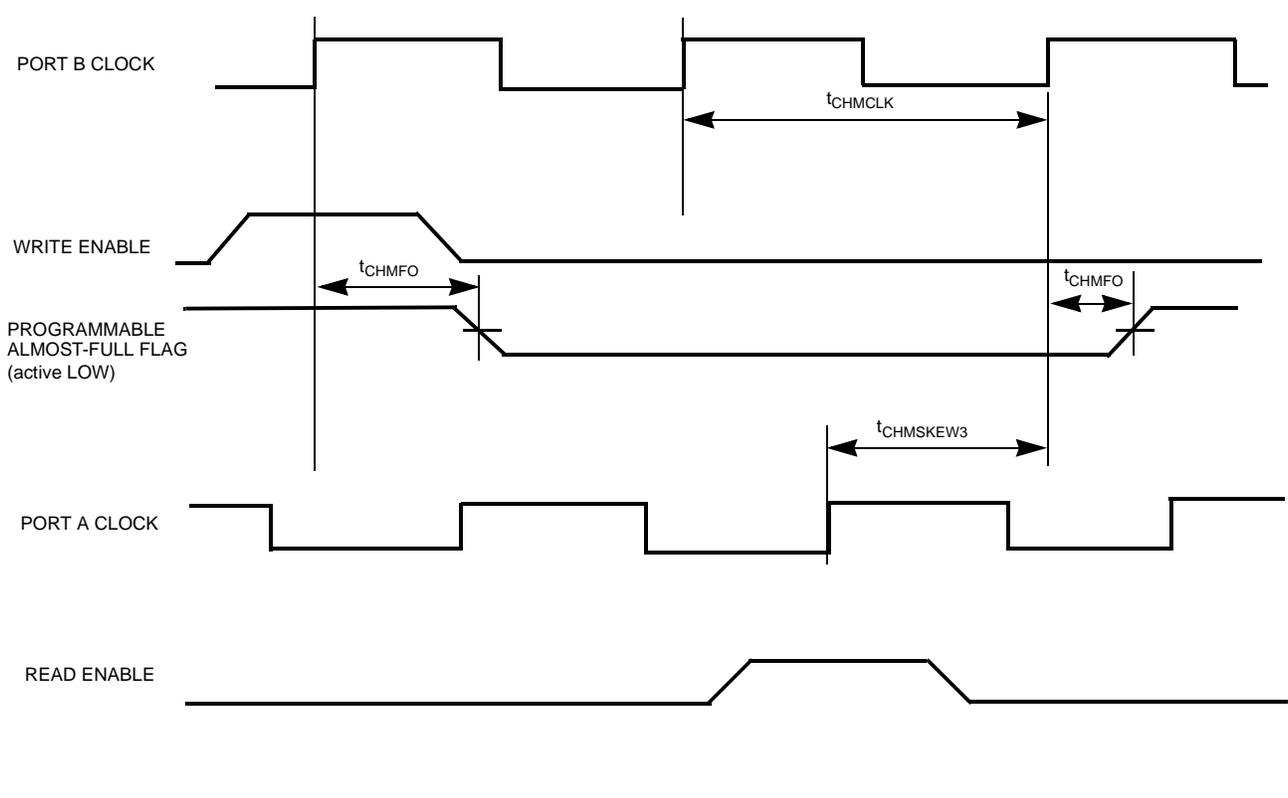
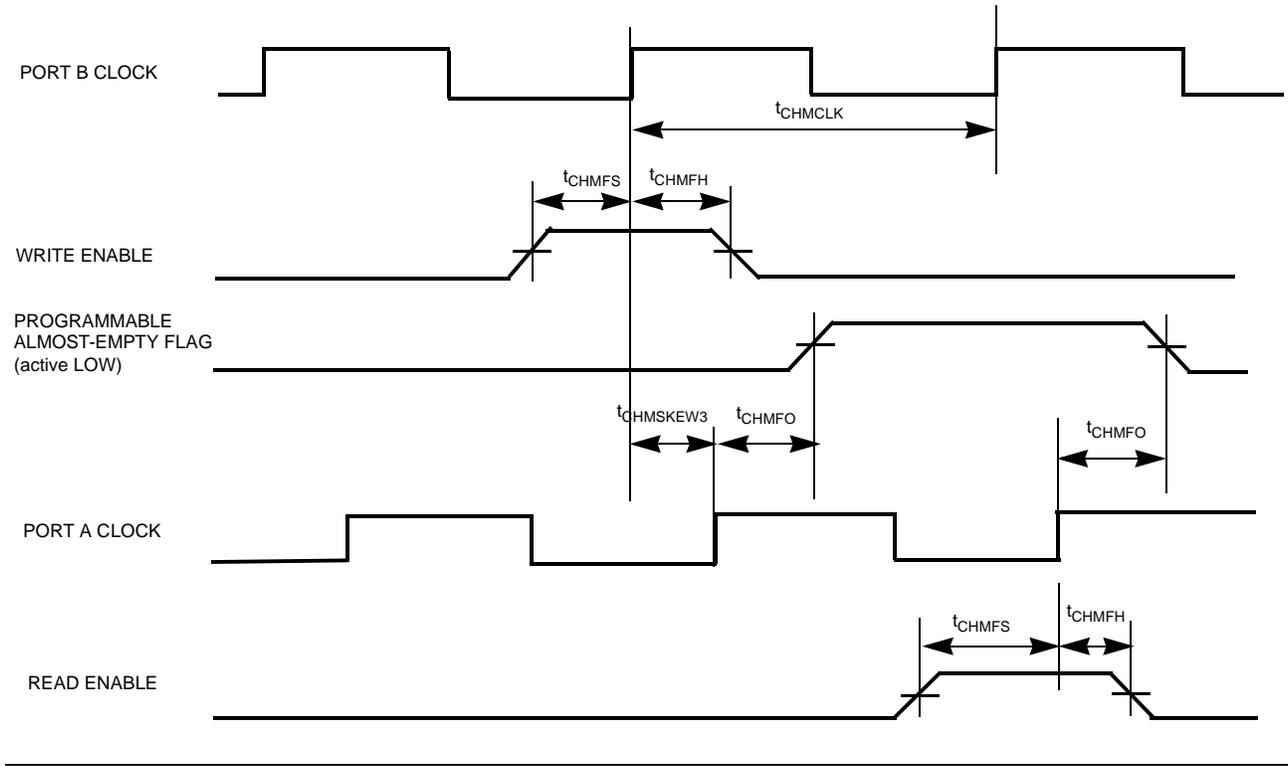
Switching Waveforms (continued)

Channel Memory Synchronous FIFO Full/Read Timing



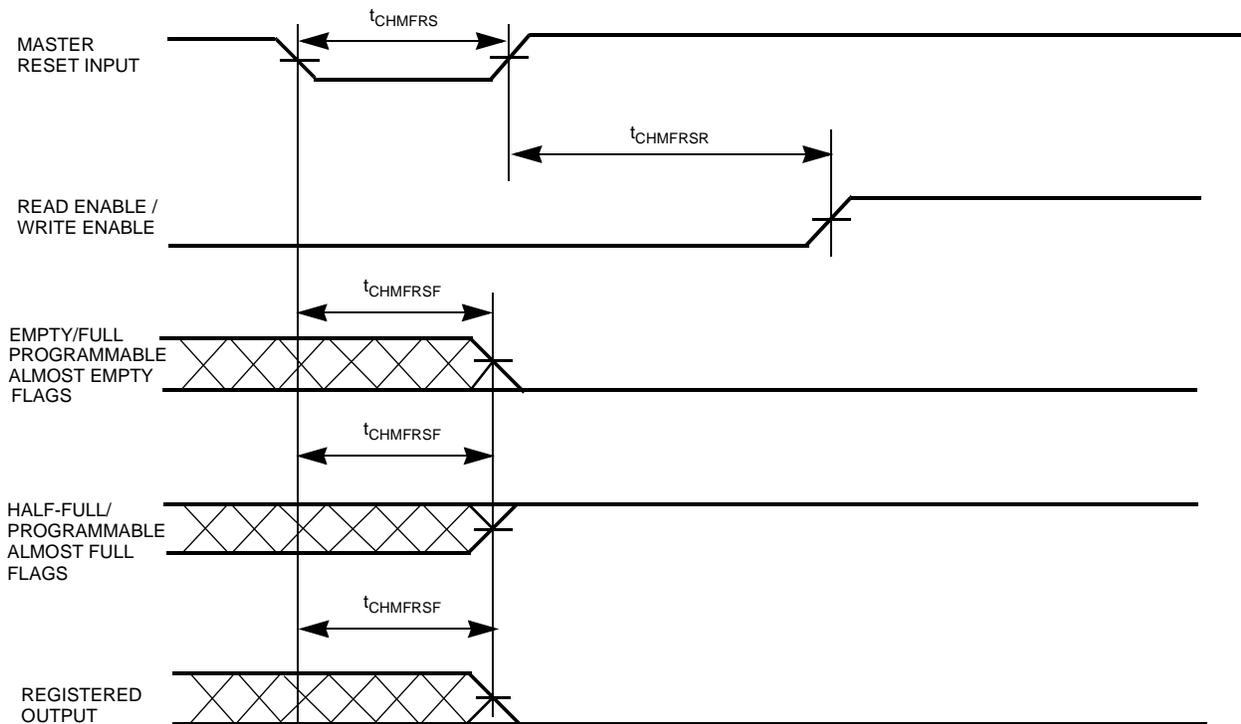
Switching Waveforms (continued)

Channel Memory Synchronous FIFO Programmable Flag Timing



Switching Waveforms (continued)

Channel Memory Synchronous FIFO Master Reset Timing



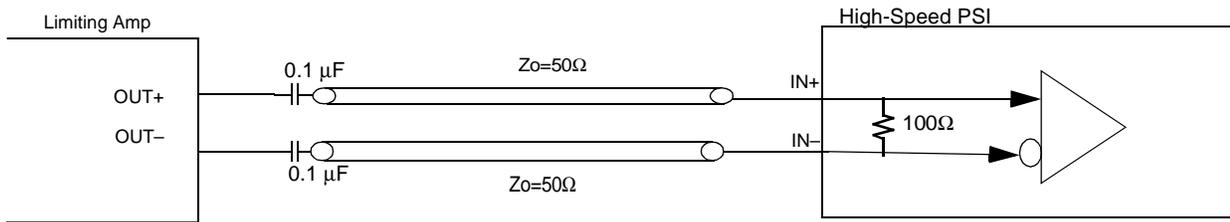


Figure 17. Serial Input Termination.

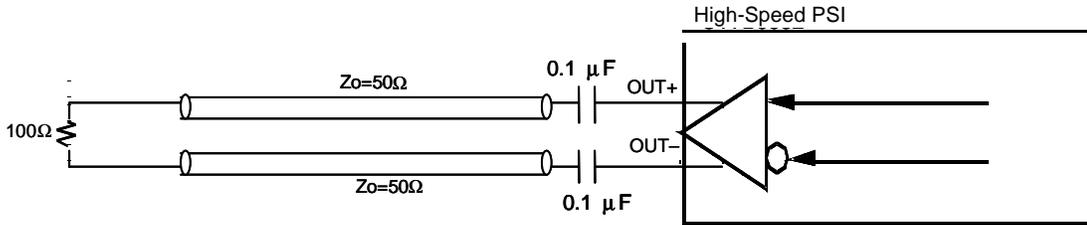


Figure 18. Serial Output Termination.

Pin and Signal Description

Name	Function	Signal Description
Standard Device Signals		
CCLK	Output	Configuration Clock for serial interface with the external boot PROM
Config_Done	Output	Flag indicating that configuration is complete
Data	Input	Pin to receive configuration data from the external boot PROM
GCLK0-1	Input	Global Input Clock signals 0 through 3
CCE	Output	Chip select for the external boot PROM
GCTL0-3	Input	Global Control signals 0 through 3
IO/V _{REF0}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 0
IO/V _{REF1}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 1
IO/V _{REF2}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 2
IO/V _{REF3}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 3
IO/V _{REF4}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 4
IO/V _{REF5}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 5
IO/V _{REF6}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 6
IO/V _{REF7}	Input/Output	Dual function pin: I/O or Reference Voltage for Bank 7
IO	Input/Output	Input or Output pin
IO6/Lock	Input/Output	Dual function pin: I/O in Bank 6 or PLL lock output signal
MSEL	Input	Mode Select Pin
Reconfig	Input	Pin to start configuration of PSI
Reset	Output	Reset signal to interface with the external boot PROM
TCLK	Input	JTAG Test Clock
TDI	Input	JTAG Test Data In
TDO	Output	JTAG Test Data Out
TMS	Input	JTAG Test Mode Select
Transmit Path Signals		
TXD[15:0]	Internal	Parallel Transmit Data Inputs. A 16-bit word, sampled by TXCLK [↑] . TXD[15] is the most significant bit (the first bit transmitted)
TXCLK	Internal	Parallel Transmit Data Input Clock. Divide by 16 of the selected transmit bit-rate clock
Receive Path Signals		
RXD[15:0]	Internal	Parallel Receive Data Output. These outputs change following RXCLK [↓] . RXD[15] is the most significant bit of the output word, and is received first on the serial interface
RXCLK	Internal	Receive Clock Output. Divide by 16 of the bit-rate clock extracted from the received serial stream
CM_SER	Analog	Common Mode Termination. Capacitor shunt to V _{SS} for common mode noise
RXCN1	Analog	Receive Loop Filter Capacitor (Negative)
RXCN2	Analog	Receive Loop Filter Capacitor (Negative)
RXCP1	Analog	Receive Loop Filter Capacitor (Positive)
RXCP2	Analog	Receive Loop Filter Capacitor (Positive)
Transceiver Control and Status Signals		
REFCLK _±	Differential LVPECL input	Reference Clock. This clock input is used as the timing reference for the transmit and receive PLLs. A derivative of this input clock may also be used to clock the transmit parallel interface
LFI	Internal	Line Fault Indicator Output Signal. When LOW, this signal indicates that the selected receive data stream has been detected as invalid by either a LOW input on SD, or by the receive VCO being operated outside its specified limits



Pin and Signal Description (continued)

Name	Function	Signal Description
RESET	Internal	Reset for all logic functions except the transmit FIFO
LOCKREF	Internal	Receive PLL Lock to Reference Input Signal. When LOW, the receive PLL locks to REFCLK instead of the received serial data stream
SD	LVTTTL input	Signal Detect. When LOW, the receive PLL locks to REFCLK instead of the received serial data stream
FIFO_ERR	Internal	Transmit FIFO Error Output Signal. When HIGH the transmit FIFO has either under or overflowed. The FIFO must be reset to clear the error indication
FIFO_RST	Internal	Transmit FIFO Reset Input Signal. When LOW, the in and out pointers of the transmit FIFO are set to maximum separation
PWRDN	Internal	Device Power Down Input Signal. When LOW, the logic and drivers are all disabled and placed into a standby condition where only minimal power is dissipated
Transceiver Loop Control Signals		
DIAGLOOP	Internal	Diagnostic Loopback Control Input Signal. When HIGH, transmit data is routed through the receive clock and data recovery and presented at the RXD[15:0] outputs. When LOW, received serial data is routed through the receive clock and data recovery and presented at the RXD[15:0] outputs
LINELOOP	Internal	Line Loopback Control Input Signal. When HIGH, received serial data is looped back from receive to transmit after being reclocked by a recovered clock. When LINELOOP is LOW, the data passed to the OUT± line driver is controlled by LOOPA. When both LINELOOP and LOOPA are LOW, the data passed to the OUT± line driver is generated in the transmit shifter
LOOPA	Internal	Analog Line Loopback Input Signal. When LINELOOP is LOW and LOOPA is HIGH, received serial data is looped back from receive input buffer to transmit output buffer, but is not routed through the clock and data recovery PLL. When LOOPA is LOW, the data passed to the OUT± line driver is controlled by LINELOOP
LOOPTIME	Internal	Loop Time Mode Input Signal. When HIGH, the extracted receive bit-clock replaces transmit bit-clock. When LOW, the REFCLK input is multiplied by 16 to generate the transmit bit clock
Serial I/O		
OUT± (OUTP/OUTN)	Differential CML output	Differential Serial Data Output. This differential CML output (+3.3V referenced) is capable of driving terminated 50Ω transmission lines or commercial fiberoptic transmitter modules
IN±	Differential CML input	Differential Serial Data Input. This differential input accept the serial data stream for deserialization and clock extraction
Power		
V _{CC}	Power	+3.3V Supply (operating voltage)
GND	Ground	Signal and Power Ground
V _{CCQ}		+3.3V Quiet Power
V _{SSQ}		Quiet Ground
V _{DDQ}		+1.5V Supply for HSTL Outputs
V _{CCIO0}	Power	V _{CC} for I/O bank 0
V _{CCIO1}	Power	V _{CC} for I/O bank 1
V _{CCIO2}	Power	V _{CC} for I/O bank 2
V _{CCIO3}	Power	V _{CC} for I/O bank 3
V _{CCIO4}	Power	V _{CC} for I/O bank 4
V _{CCIO5}	Power	V _{CC} for I/O bank 5
V _{CCIO6}	Power	V _{CC} for I/O bank 6
V _{CCIO7}	Power	V _{CC} for I/O bank 7
V _{CCJTAG}	Power	V _{CC} for JTAG pins
V _{CCCNFG}	Power	V _{CC} for Configuration port



Programmable Serial Interface (High Speed Devices)

PRELIMINARY

Pin and Signal Description (continued)

Name	Function	Signal Description
V _{CC} PLL	Power	V _{CC} for logic PLL
V _{CEP}	Power	V _{CC} for the Self-Boot™ solution embedded boot PROM

Pin Configurations

456-Ball BGA (25G01K100)

Top View

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26			
A	GND	HSTL-REF	IO7	IO7	IO7	IO7	HSTL-REF	IO7	IO7	IO7	HSTL-REF	HSTL-REF	IO6	IO6	IO6	HSTL-REF	IO5	IO5	IO5	IO/VRE F5	IO5	IO5	IO5	IO/VRE F5	IO5	GND	A		
B	HSTL-REF	HSTL-REF	IO7	HSTL-REF	IO7	IO7	IO7	VDDQ	IO7	HSTL-REF	IO6	IO6	IO6	IO6	IO6	IO6	IO5	IO5	IO5	IO5	IO5	IO/VRE F5	IO5	IO5	IO5	IO5	B		
C	IO0	IO7	IO7	IO7	VDDQ	VCC	VCCVC C	IO7	GCTL3	IO7	VDDQ	VDDQ	VDDQ	HSTL-REF	IO6	IO6	IO5	IO5	IO5	GCTL2	GCTL1	IO5	IO5	IO5	TDO	TCK	C		
D	IO0	IO0	IO0	IO7	VDDQ	VDDQ	VDDQ	GND	HSTL-REF	IO7	NC	VDDQ	VCC	IO6	IO6	IO6	VCPLL	VDDQ	VDDQ	VDDQ	VCC	NC	GCLK1	IO5	TMS	TDI	D		
E	IO0	IO0	IO0	GCTL0	GND	GND	IO7	GND	GND	HSTL-REF	IO6	IO6	IO6	IO6	IO6	IO6	IO/VRE F5	IO5	IO5	IO5	IO5	IO5	VCCO5	VCCO5	VCCO5	VCJTG	E		
F	IO/VRE F0	IO0	IO0	VCC	GND																	NC	NC	NC	NC	NC	F		
G	IO0	IO/VRE F0	VCC	VCCO0	GCLK0																	NC	NC	NC	NC	NC	G		
H	IO0	IO0	VCC	VCCO0	GND																	NC	VSSQ	VSSQ	NC	NC	H		
J	IO0	IO0	VCC	VCCO0	GND																	NC	VSSQ	VSSQ	VSSQ	NC	J		
K	IO0	IO0	IO0	IO0	VCC																	VSSQ	VSSQ	VSSQ	NC	NC	K		
L	IO0	IO0	IO0	GND	IO0	GND						GNPLL												NC	NC	NC	NC	NC	L
M	IO0	IO/VRE F0	IO0	GND	IO0	GND						GND												SD	RXCN1	RXCP1	RXCN2	RXCP2	M
N	VCC	IO0	IO0	GND	IO/VRE F0	GND						GND												NC	VCCQ	VCCQ	VCCQ	VCCQ	N
P	IO1	IO1	IO1	IO1	IO0	GND						GND												NC	VSSQ	VSSQ	INP	INN	P
R	IO1	IO1	IO1	VCCO1	GND	GND						GND												NC	VSSQ	VSSQ	VSSQ	CMSER	R
T	IO/VRE F1	IO/VRE F1	IO1	IO1	IO1	GND						GND												VSSQ	VSSQ	VSSQ	OUTP	OUTN	T
U	IO1	IO1	IO1	GND	GND																	NC	VCCQ	VCCQ	VCCQ	VCCQ	U		
V	IO1	IO1	IO/VRE F1	IO1	GND																	REF-CLKP	VCCO4	IO4	IO4	VCCO4	V		
W	IO1	IO1	IO1	IO1	GND																	REF-CLKN	VCCO4	IO4	IO4	IO4	W		
Y	IO1	IO1	VCEP	IO1	IO1																	IO4	VCEP	IO4	IO4	IO/VRE F4	Y		
AA	IO1	IO1	VCCO1	IO/VRE F1	GND																	IO4	NC	IO4	IO4	IO4	AA		
AB	GND	CDONE	VCCO1	IO1	IO2	GND	GND	GND	IO2	IO/VRE F2	IO2	IO2	IO3	IO3	GND	IO3	GND	GND	GND	IO3	IO3	IO3	IO3	IO3	IO3	IO3	AB		
AC	CDATA	RECON FIG	IO2	IO2	VCCFG	VCCO2	VCCO2	VCCO2	VCCO2	NC	IO2	IO2	IO2	VDDQ	VCCO3	VCCO3	IO3	IO3	IO/VRE F3	NC	NC	VCCO4	IO/VRE F4	IO/VRE F4	IO4	IO4	AC		
AD	CRST	CCLK	IO2	IO2	IO2	IO2	IO2	NC	VDDQ	VDDQ	IO2	IO2	IO/VRE F2	IO2	IO3	IO3	IO3	IO3	IO3	VCC	VCCO3	VCCO3	IO/VRE F3	IO3	IO3	IO3	AD		
AE	CCE	MSEL	IO/VRE F2	IO2	IO/VRE F2	IO2	IO2	IO2	IO2	IO2	IO/VRE F2	IO2	IO2	IO2	IO3	IO3	IO3	IO3	IO3	IO3	IO3	IO/VRE F3	IO3	IO3	IO3	IO/VRE F3	AE		
AF	GND	IO2	IO2	IO2	IO2	IO/VRE F2	IO2	IO2	IO2	IO2	IO2	IO2	VCC	IO/VRE F3	IO3	IO3	IO/VRE F3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	GND	AF		



Programmable Serial Interface (High Speed Devices)

PRELIMINARY

456-Ball BGA (25G02K100)

Top View

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26																															
A	GND	IO/VREF7	NC	NC	NC	NC	IO/VREF7	NC	NC	IO7	IO/VREF6	IO/VREF6	NC	NC	NC	IO/VREF6	IO5	IO5	IO5	IO/VREF5	IO5	IO5	IO5	IO/VREF5	IO5	IO5	GND	A																													
B	IO/VREF7	IO/VREF7	NC	IO/VREF7	NC	NC	VDDQ	IO7	IO/VREF6	NC	NC	IO6	NC	NC	NC	IO5	IO5	IO5	IO5	IO5	IO5	IO/VREF5	IO5	IO5	IO5	IO5	IO5	B																													
C	IO0	NC	NC	NC	VDDQ	VCC	VCC	NC	GCTL3	IO7	VDDQ	VDDQ	VDDQ	IO/VREF6	NC	NC	IO5	IO5	IO5	GCTL2	GCTL1	IO5	IO5	IO5	TDO	TCK	C																														
D	IO0	IO0	IO0	NC	VDDQ	VDDQ	VDDQ	GND	IO/VREF7	IO7	VCC	VDDQ	VCC	NC	NC	IO6	VCPLL	VDDQ	VDDQ	VDDQ	VCC	VDDQ	NC	IO5	TMS	TDI	D																														
E	IO0	IO0	IO0	GCTL0	GND	GND	NC	GND0	GND	IO/VREF6	NC	NC	NC	IOP6	NC	IO6	IO/VREF5	IO5	IO5	IO5	IO5	IO5	VCC05	VCC05	VCC05	VCJTG	E																														
F	IO/VREF0	IO0	IO0	VCC	GND																	SD_B	RXCP2_B	RXCN2_B	RXCP1_B	RXCN1_B	F																														
G	IO0	IO/VREF0	VCC	VCC00	GCLK0																	VDDQ	VCCQ	VCCQ	VCCQ	VCCQ	G																														
H	IO0	IO0	VCC	VCC00	GND																	NC	VSSQ	VSSQ	INP_B	INN_B	H																														
J	IO0	IO0	VCC	VCC00	GND																	NC	VSSQ	VSSQ	VSSQ	CM SER_B	J																														
K	IO0	IO0	IO0	IO0	VCC																	VSSQ	VSSQ	VSSQ	OUTN_B	OUTP_B	K																														
L	IO0	IO0	IO0	GND	IO0	<table border="1" style="margin: auto;"> <tr><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GNPLL</td></tr> <tr><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td></tr> <tr><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td></tr> <tr><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td></tr> <tr><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td><td>GND</td></tr> </table>										GND	GND	GND	GND	GND	GNPLL	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND							VDDQ	VCCQ	VCCQ	VCCQ	VCCQ	L
GND	GND	GND	GND	GND	GNPLL																																																				
GND	GND	GND	GND	GND	GND																																																				
GND	GND	GND	GND	GND	GND																																																				
GND	GND	GND	GND	GND	GND																																																				
GND	GND	GND	GND	GND	GND																																																				
M	IO0	IO/VREF0	IO0	GND	IO0																	SD	RXCN1	RXCP1	RXCN2	RXCP2	M																														
N	VCC	IO0	IO0	GND	IO/VREF0																	VDDQ	VCCQ	VCCQ	VCCQ	VCCQ	N																														
P	IO1	IO1	IO1	IO1	IO0																	NC	VSSQ	VSSQ	INP	INN	P																														
R	IO1	IO1	IO1	VCC01	GND0																	NC	VSSQ	VSSQ	VSSQ	CM SER	R																														
T	IO/VREF1	IO/VREF1	IO1	IO1	IO1																	VSSQ	VSSQ	VSSQ	OUTP	OUTN	T																														
U	IO1	IO1	IO1	GND	GND																	VDDQ	VCCQ	VCCQ	VCCQ	VCCQ	U																														
V	IO1	IO1	IO/VREF1	IO1	GND																	REF-CLKP	VCC04	IO4	IO4	VCC04	V																														
W	IO1	IO1	IO1	IO1	GND																	REF-CLKN	VCC04	IO4	NC	NC	W																														
Y	IO1	IO1	VCEP	IO1	IO1																	IO4	VCEP	IO4	NC	NC	Y																														
AA	IO1	IO1	VCC01	IO/VREF1	GND0																	IO4	VCC	IO4	NC	NC	AA																														
AB	GND	CDONE	VCC01	IO1	IO2	GND	GND	GND	IO2	IO/VREF2	IO2	IO2	IO3	IO3	GND	IO3	GND	GND	GND	IO3	IO3	IO3	IO4	IO4	NC	NC	AB																														
AC	CDATA	RECON FIG	IO2	IO2	VCCFG	VCC02	VCC02	VCC02	VCC02	VCC	IO2	IO2	IO2	VDDQ	VCC03	VCC03	IO3	IO3	IO/VREF3	VCC	VDDQ	VCC04	IO/VREF4	IO/VREF4	NC	NC	AC																														
AD	CRST	CCLK	IO2	IO2	IO2	IO2	IO2	VCC	VDDQ	VDDQ	IO2	IO2	IO/VREF2	IO2	IO3	IO3	IO3	IO3	IO3	VCC	VCC03	VCC03	IO/VREF3	IO3	IO3	IO3	AD																														
AE	CCE	MSEL	IO/VREF2	IO2	IO/VREF2	IO2	IO2	IO2	IO2	IO2	IO/VREF2	IO2	IO2	IO2	IO3	IO3	IO3	IO3	IO3	IO3	IO/VREF3	IO3	IO3	IO3	IO/VREF3	IO3	AE																														
AF	GND	IO2	IO2	IO2	IO2	IO2	IO/VREF2	IO2	IO2	IO2	IO2	VCC	IO/VREF3	IO3	IO3	IO/VREF3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	IO3	GND	AF																													

456-Ball BGA Pin Table

Pin	25G01K100	25G02K100
A1	GND	GND
A2	HSTLREF	IO/VREF7
A3	IO7	NC
A4	IO7	NC
A5	IO7	NC
A6	IO7	NC
A7	HSTLREF	IO/VREF7
A8	IO7	NC
A9	IO7	NC
A10	IO7	IO7
A11	HSTLREF	IO/VREF6
A12	HSTLREF	IO/VREF6
A13	IO6	NC
A14	IO6	NC
A15	IO6	NC
A16	HSTLREF	IO/VREF6
A17	IO5	IO5
A18	IO5	IO5
A19	IO5	IO5
A20	IO/VREF5	IO/VREF5
A21	IO5	IO5
A22	IO5	IO5
A23	IO5	IO5
A24	IO/VREF5	IO/VREF5
A25	IO5	IO5
A26	GND	GND
B1	HSTLREF	IO/VREF7
B2	HSTLREF	IO/VREF7
B3	IO7	NC
B4	HSTLREF	IO/VREF7
B5	IO7	NC
B6	IO7	NC
B7	IO7	NC
B8	VDDQ	VDDQ
B9	IO7	IO7
B10	HSTLREF	IO/VREF6
B11	IO6	NC
B12	IO6	NC
B13	IO6	IO6
B14	IO6	NC

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
B15	IO6	NC
B16	IO6	NC
B17	IO5	IO5
B18	IO5	IO5
B19	IO5	IO5
B20	IO5	IO5
B21	IO5	IO5
B22	IO/VREF5	IO/VREF5
B23	IO5	IO5
B24	IO5	IO5
B25	IO5	IO5
B26	IO5	IO5
C1	IO0	IO0
C2	IO7	NC
C3	IO7	NC
C4	IO7	NC
C5	VDDQ	VDDQ
C6	VCC	VCC
C7	VCC	VCC
C8	IO7	NC
C9	GCTL3	GCTL3
C10	IO7	IO7
C11	VDDQ	VDDQ
C12	VDDQ	VDDQ
C13	VDDQ	VDDQ
C14	HSTLREF	IO/VREF6
C15	IO6	NC
C16	IO6	NC
C17	IO5	IO5
C18	IO5	IO5
C19	IO5	IO5
C20	GCTL2	GCTL2
C21	GCTL1	GCTL1
C22	IO5	IO5
C23	IO5	IO5
C24	IO5	IO5
C25	TDO	TDO
C26	TCK	TCK
D1	IO0	IO0
D2	IO0	IO0
D3	IO0	IO0



Programmable Serial Interface (High Speed Devices)

PRELIMINARY

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
D4	IO7	NC
D5	VDDQ	VDDQ
D6	VDDQ	VDDQ
D7	VDDQ	VDDQ
D8	GND	GND
D9	HSTLREF	IO/REF7
D10	IO7	IO7
D11	NC	VCC
D12	VDDQ	VDDQ
D13	VCC	VCC
D14	IO6	NC
D15	IO6	NC
D16	IO6	IO6
D17	VCPLL	VCPLL
D18	VDDQ	VDDQ
D19	VDDQ	VDDQ
D20	VDDQ	VDDQ
D21	VCC	VCC
D22	NC	VDDQ
D23	GCLK1	NC
D24	IO5	IO5
D25	TMS	TMS
D26	TDI	TDI
E1	IO0	IO0
E2	IO0	IO0
E3	IO0	IO0
E4	GCTL0	GCTL0
E5	GND	GND
E6	GND	GND
E7	IO7	NC
E8	GND	GNDO
E9	GND	GND
E10	HSTLREF	IO/REF6
E11	IO6	NC
E12	IO6	NC
E13	IO6	NC
E14	IOP6	IOP6
E15	IO6	NC
E16	IO6	IO6
E17	IO/REF5	IO/REF5
E18	IO5	IO5

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
E19	IO5	IO5
E20	IO5	IO5
E21	IO5	IO5
E22	IO5	IO5
E23	VCCO5	VCCO5
E24	VCCO5	VCCO5
E25	VCCO5	VCCO5
E26	VCJTG	VCJTG
F1	IO/VREF0	IO/VREF0
F2	IO0	IO0
F3	IO0	IO0
F4	VCC	VCC
F5	GND	GND
F22	NC	SD_B
F23	NC	RXCP2_B
F24	NC	RXCN2_B
F25	NC	RXCP1_B
F26	NC	RXCN1_B
G1	IO0	IO0
G2	IO/VREF0	IO/VREF0
G3	VCC	VCC
G4	VCCO0	VCCO0
G5	GCLK0	GCLK0
G22	NC	VDDQ
G23	NC	VCCQ
G24	NC	VCCQ
G25	NC	VCCQ
G26	NC	VCCQ
H1	IO0	IO0
H2	IO0	IO0
H3	VCC	VCC
H4	VCCO0	VCCO0
H5	GND	GND
H22	NC	NC
H23	VSSQ	VSSQ
H24	VSSQ	VSSQ
H25	NC	INP_B
H26	NC	INN_B
J1	IO0	IO0
J2	IO0	IO0
J3	VCC	VCC



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456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
J4	VCCO0	VCCO0
J5	GND	GND
J22	NC	NC
J23	VSSQ	VSSQ
J24	VSSQ	VSSQ
J25	VSSQ	VSSQ
J26	NC	CMSER_B
K1	IO0	IO0
K2	IO0	IO0
K3	IO0	IO0
K4	IO0	IO0
K5	VCC	VCC
K22	VSSQ	VSSQ
K23	VSSQ	VSSQ
K24	VSSQ	VSSQ
K25	NC	OUTN_B
K26	NC	OUTP_B
L1	IO0	IO0
L2	IO0	IO0
L3	IO0	IO0
L4	GND	GND
L5	IO0	IO0
L11	GND	GND
L12	GND	GND
L13	GND	GND
L14	GND	GND
L15	GND	GND
L16	GNPLL	GNPLL
L22	NC	VDDQ
L23	NC	VCCQ
L24	NC	VCCQ
L25	NC	VCCQ
L26	NC	VCCQ
M1	IO0	IO0
M2	IO/VREF0	IO/VREF0
M3	IO0	IO0
M4	GND	GND
M5	IO0	IO0
M11	GND	GND
M12	GND	GND
M13	GND	GND

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
M14	GND	GND
M15	GND	GND
M16	GND	GND
M22	SD	SD
M23	RXCN1	RXCN1
M24	RXCP1	RXCP1
M25	RXCN2	RXCN2
M26	RXCP2	RXCP2
N1	VCC	VCC
N2	IO0	IO0
N3	IO0	IO0
N4	GND	GND
N5	IO/VREF0	IO/VREF0
N11	GND	GND
N12	GND	GND
N13	GND	GND
N14	GND	GND
N15	GND	GND
N16	GND	GND
N22	NC	VDDQ
N23	VCCQ	VCCQ
N24	VCCQ	VCCQ
N25	VCCQ	VCCQ
N26	VCCQ	VCCQ
P1	IO1	IO1
P2	IO1	IO1
P3	IO1	IO1
P4	IO1	IO1
P5	IO0	IO0
P11	GND	GND
P12	GND	GND
P13	GND	GND
P14	GND	GND
P15	GND	GND
P16	GND	GND
P22	NC	NC
P23	VSSQ	VSSQ
P24	VSSQ	VSSQ
P25	INP	INP
P26	INN	INN
R1	IO1	IO1



456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
R2	IO1	IO1
R3	IO1	IO1
R4	VCCO1	VCCO1
R5	GND	GNDO
R11	GND	GND
R12	GND	GND
R13	GND	GND
R14	GND	GND
R15	GND	GND
R16	GND	GND
R22	NC	NC
R23	VSSQ	VSSQ
R24	VSSQ	VSSQ
R25	VSSQ	VSSQ
R26	CM SER	CM SER
T1	IO/VREF1	IO/VREF1
T2	IO/VREF1	IO/VREF1
T3	IO1	IO1
T4	IO1	IO1
T5	IO1	IO1
T11	GND	GND
T12	GND	GND
T13	GND	GND
T14	GND	GND
T15	GND	GND
T16	GND	GND
T22	VSSQ	VSSQ
T23	VSSQ	VSSQ
T24	VSSQ	VSSQ
T25	OUTP	OUTP
T26	OUTN	OUTN
U1	IO1	IO1
U2	IO1	IO1
U3	IO1	IO1
U4	GND	GND
U5	GND	GND
U22	NC	VDDQ
U23	VCCQ	VCCQ
U24	VCCQ	VCCQ
U25	VCCQ	VCCQ
U26	VCCQ	VCCQ

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
V1	IO1	IO1
V2	IO1	IO1
V3	IO/VREF1	IO/VREF1
V4	IO1	IO1
V5	GND	GND
V22	REFCLKP	REFCLKP
V23	VCCO4	VCCO4
V24	IO4	IO4
V25	IO4	IO4
V26	VCCO4	VCCO4
W1	IO1	IO1
W2	IO1	IO1
W3	IO1	IO1
W4	IO1	IO1
W5	GND	GND
W22	REFCLKN	REFCLKN
W23	VCCO4	VCCO4
W24	IO4	IO4
W25	IO4	IO4
W26	IO4	IO4
Y1	IO1	IO1
Y2	IO1	IO1
Y3	VCEP	VCEP
Y4	IO1	IO1
Y5	IO1	IO1
Y22	IO4	IO4
Y23	VCEP	VCEP
Y24	IO4	IO4
Y25	IO4	IO1
Y26	IO/VREF4	IO1
AA1	IO1	IO1
AA2	IO1	IO1
AA3	VCCO1	VCCO1
AA4	IO/VREF1	IO/VREF1
AA5	GND	GNDO
AA22	IO4	IO4
AA23	NC	VCC
AA24	IO4	IO4
AA25	IO4	NC
AA26	IO4	NC
AB1	GND	GND



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456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
AB2	CDONE	CDONE
AB3	VCCO1	VCCO1
AB4	IO1	IO1
AB5	IO2	IO2
AB6	GND	GND
AB7	GND	GND
AB8	GND	GND
AB9	IO2	IO2
AB10	IO/VREF2	IO/VREF2
AB11	IO2	IO2
AB12	IO2	IO2
AB13	IO3	IO3
AB14	IO3	IO3
AB15	GND	GND
AB16	IO3	IO3
AB17	GND	GND
AB18	GND	GND
AB19	GND	GND
AB20	IO3	IO3
AB21	IO3	IO3
AB22	IO3	IO3
AB23	IO4	IO4
AB24	IO4	IO4
AB25	IO4	NC
AB26	IO4	NC
AC1	CDATA	CDATA
AC2	RECONFIG	RECONFIG
AC3	IO2	IO2
AC4	IO2	IO2
AC5	VCCFG	VCCFG
AC6	VCCO2	VCCO2
AC7	VCCO2	VCCO2
AC8	VCCO2	VCCO2
AC9	VCCO2	VCCO2
AC10	NC	VCC
AC11	IO2	IO2
AC12	IO2	IO2
AC13	IO2	IO2
AC14	VDDQ	VDDQ
AC15	VCCO3	VCCO3
AC16	VCCO3	VCCO3

456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
AC17	IO3	IO3
AC18	IO3	IO3
AC19	IO/VREF3	IO/VREF3
AC20	NC	VCC
AC21	NC	VDDQ
AC22	VCCO4	VCCO4
AC23	IO/VREF4	IO/VREF4
AC24	IO/VREF4	IO/VREF4
AC25	IO4	NC
AC26	IO4	NC
AD1	CRST	CRST
AD2	CCLK	CCLK
AD3	IO2	IO2
AD4	IO2	IO2
AD5	IO2	IO2
AD6	IO2	IO2
AD7	IO2	IO2
AD8	NC	VCC
AD9	VDDQ	VDDQ
AD10	VDDQ	VDDQ
AD11	IO2	IO2
AD12	IO2	IO2
AD13	IO/VREF2	IO/VREF2
AD14	IO2	IO2
AD15	IO3	IO3
AD16	IO3	IO3
AD17	IO3	IO3
AD18	IO3	IO3
AD19	IO3	IO3
AD20	VCC	VCC
AD21	VCCO3	VCCO3
AD22	VCCO3	VCCO3
AD23	IO/VREF3	IO/VREF3
AD24	IO3	IO3
AD25	IO3	IO3
AD26	IO3	IO3
AE1	CCE	CCE
AE2	MSEL	MSEL
AE3	IO/VREF2	IO/VREF2
AE4	IO2	IO2
AE5	IO/VREF2	IO/VREF2



456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
AE6	IO2	IO2
AE7	IO2	IO2
AE8	IO2	IO2
AE9	IO2	IO2
AE10	IO2	IO2
AE11	IO/VREF2	IO/VREF2
AE12	IO2	IO2
AE13	IO2	IO2
AE14	IO2	IO2
AE15	IO3	IO3
AE16	IO3	IO3
AE17	IO3	IO3
AE18	IO3	IO3
AE19	IO3	IO3
AE20	IO3	IO3
AE21	IO/VREF3	IO/VREF3
AE22	IO3	IO3
AE23	IO3	IO3
AE24	IO3	IO3
AE25	IO/VREF3	IO/VREF3
AE26	IO3	IO3
AF1	GND	GND
AF2	IO2	IO2
AF3	IO2	IO2
AF4	IO2	IO2
AF5	IO2	IO2
AF6	IO2	IO2
AF7	IO/VREF2	IO/VREF2
AF8	IO2	IO2
AF9	IO2	IO2
AF10	IO2	IO2
AF11	IO2	IO2
AF12	IO2	IO2
AF13	VCC	VCC
AF14	IO/VREF3	IO/VREF3
AF15	IO3	IO3
AF16	IO3	IO3
AF17	IO/VREF3	IO/VREF3
AF18	IO3	IO3
AF19	IO3	IO3
AF20	IO3	IO3

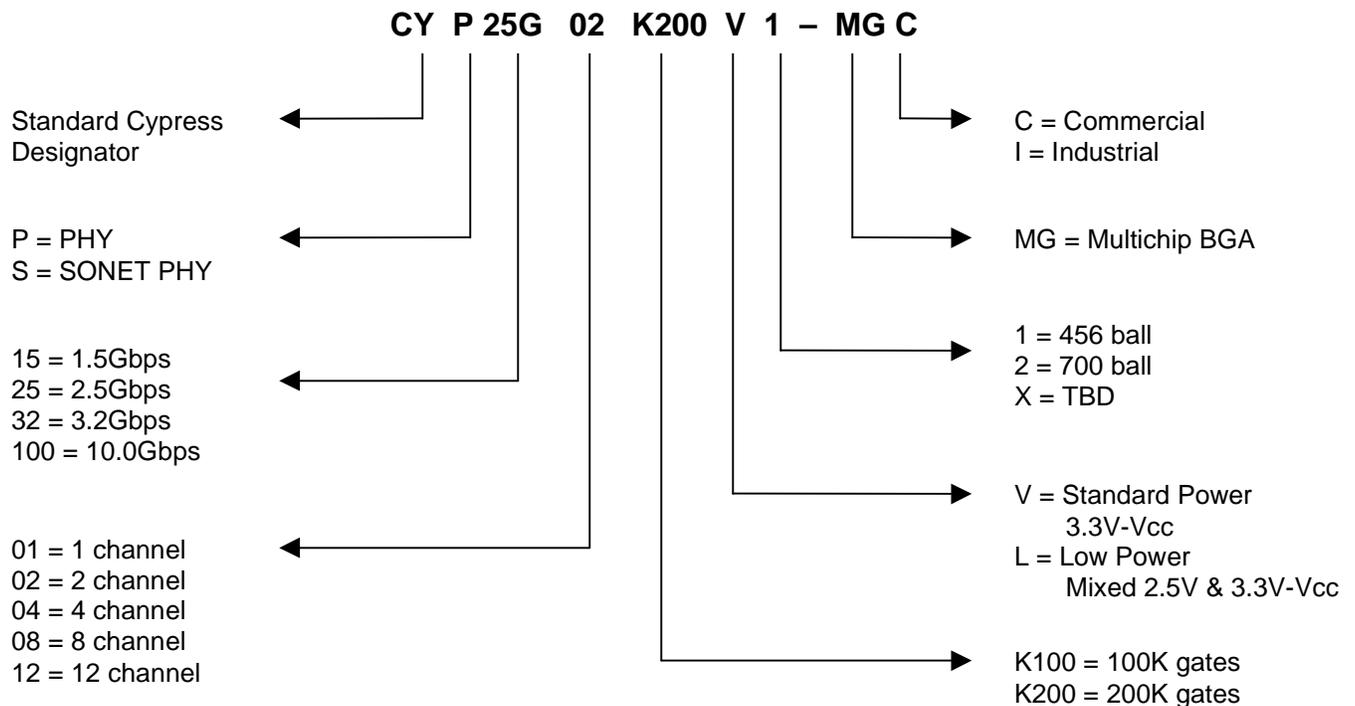
456-Ball BGA Pin Table (continued)

Pin	25G01K100	25G02K100
AF21	IO3	IO3
AF22	IO3	IO3
AF23	IO3	IO3
AF24	IO3	IO3
AF25	IO3	IO3
AF26	GND	GND



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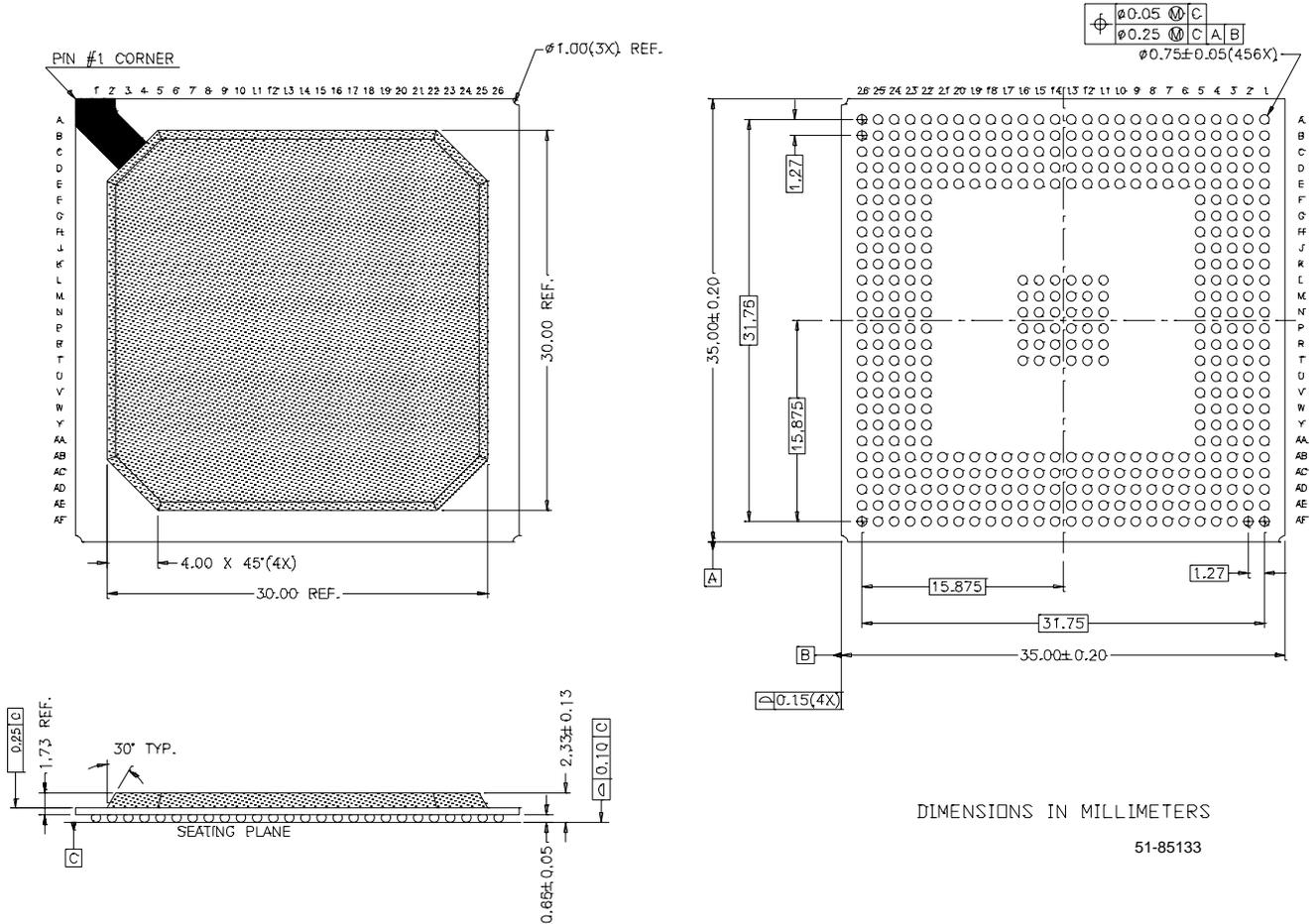


Ordering Information

Device	Channels & Link Speed	Ordering Code	Package Name	Package Type	Operating Range
25G01K100	1 x 2.5 Gbps	CYP25G01K100V1-MGC	456MGC	456-Ball Ball Grid Array	Commercial
	1 x 2.5 Gbps	CYS25G01K100V1-MGC	456MGC	456-Ball Ball Grid Array	
25G02K100	2 x 2.5 Gbps	CYP25G02K100V1-MGC	456MGC	456-Ball Ball Grid Array	Commercial
	2 x 2.5 Gbps	CYS25G02K100V1-MGC	456MGC	456-Ball Ball Grid Array	
15G04K100	4 x 0.2 - 1.5 Gbps	CYP15G04K100V1-MGC	456MGC	456-Ball Ball Grid Array	Commercial
15G04K200	4 x 0.2 - 1.5 Gbps	CYP15G04K200V2-MGC	700MGC	700-Ball Ball Grid Array	Industrial
15G08K200	8 x 0.2 - 1.5 Gbps	CYP15G08K200V2-MGC	700MGC	700-Ball Ball Grid Array	Commercial

Package Diagrams

456-Lead Ball Grid Array (35 x 35 x 2.33 mm) BG456



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Programmable Serial Interface *PRELIMINARY* (High Speed Devices)

Document Title: Programmable Serial Interface Device Family (High Speed) Programmable Bandwidth Document Number: 38-02021				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	106745	05/25/01	SZV	Change from Spec #38-01093 to 38-02021
*A	107726	06/04/01	MHW	Updated Marketing Part Numbers
*B	109064	09/07/01	MHW	Added x8 feature in PLL and CHAR data